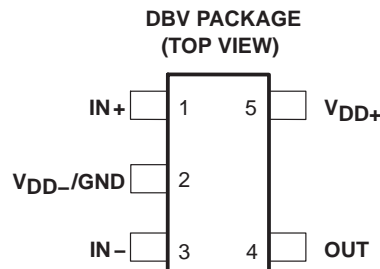


- **Output Swing Includes Both Supply Rails**
- **Low Noise . . . 19 nV/√Hz Typ at f = 1 kHz**
- **Low Input Bias Current . . . 1 pA Typ**
- **Fully Specified for Single-Supply 3-V and 5-V Operation**
- **Very Low Power . . . 110 μA Typ**
- **Common-Mode Input Voltage Range Includes Negative Rail**
- **Wide Supply Voltage Range 2.7 V to 10 V**
- **Macromodel Included**



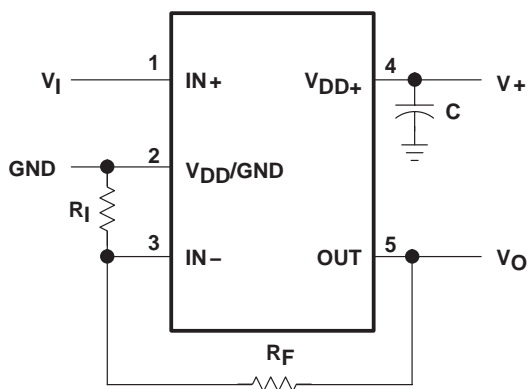
## description

The TLV2221 is a single low-voltage operational amplifier available in the SOT-23 package. It offers a compromise between the ac performance and output drive of the TLV2231 and the micropower TLV2211.

It consumes only 150 μA (max) of supply current and is ideal for battery-powered applications. The device exhibits rail-to-rail output performance for increased dynamic range in single- or split-supply applications. The TLV2221 is fully characterized at 3 V and 5 V and is optimized for low-voltage applications.

The TLV2221, exhibiting high input impedance and low noise, is excellent for small-signal conditioning for high-impedance sources, such as piezoelectric transducers. Because of the micropower dissipation levels combined with 3-V operation, these devices work well in hand-held monitoring and remote-sensing applications. In addition, the rail-to-rail output feature with single or split supplies makes this family a great choice when interfacing with analog-to-digital converters (ADCs).

With a total area of 5.6mm<sup>2</sup>, the SOT-23 package only requires one third the board space of the standard 8-pin SOIC package. This ultra-small package allows designers to place single amplifiers very close to the signal source, minimizing noise pick-up from long PCB traces. TI has also taken special care to provide a pinout that is optimized for board layout (see Figure 1). Both inputs are separated by GND to prevent coupling or leakage paths. The OUT and IN– terminals are on the same end of the board to provide negative feedback. Finally, gain setting resistors and decoupling capacitor are easily placed around the package.



**Figure 1. Typical Surface Mount Layout for a Fixed-Gain Noninverting Amplifier**



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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

# TLV2221, TLV2221Y

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#### AVAILABLE OPTIONS

$T_A$	$V_{IOmax}$ AT 25°C	PACKAGED DEVICES	SYMBOL	CHIP FORM‡ (Y)
		SOT-23 (DBV)†		
0°C to 70°C	3 mV	TLV2221CDBV	VADC	TLV2221Y
–40°C to 85°C	3 mV	TLV2221IDBV	VADI	

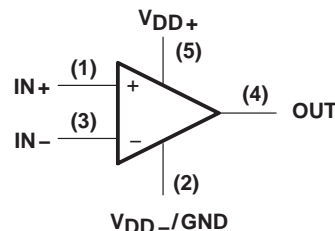
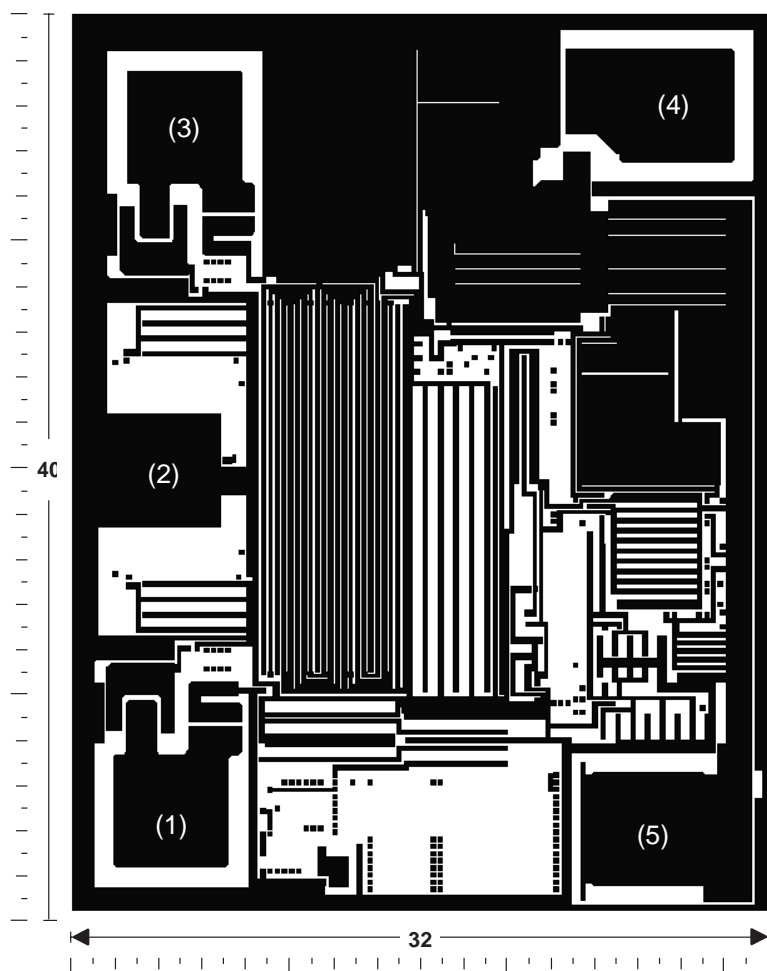
† The DBV package available in tape and reel only.

‡ Chip forms are tested at  $T_A = 25^\circ\text{C}$  only.

#### TLV2221Y chip information

This chip, when properly assembled, displays characteristics similar to the TLV2221C. Thermal compression or ultrasonic bonding may be used on the doped-aluminum bonding pads. This chip may be mounted with conductive epoxy or a gold-silicon preform.

#### BONDING PAD ASSIGNMENTS



CHIP THICKNESS: 10 MILS TYPICAL

BONDING PADS:  $4 \times 4$  MILS MINIMUM

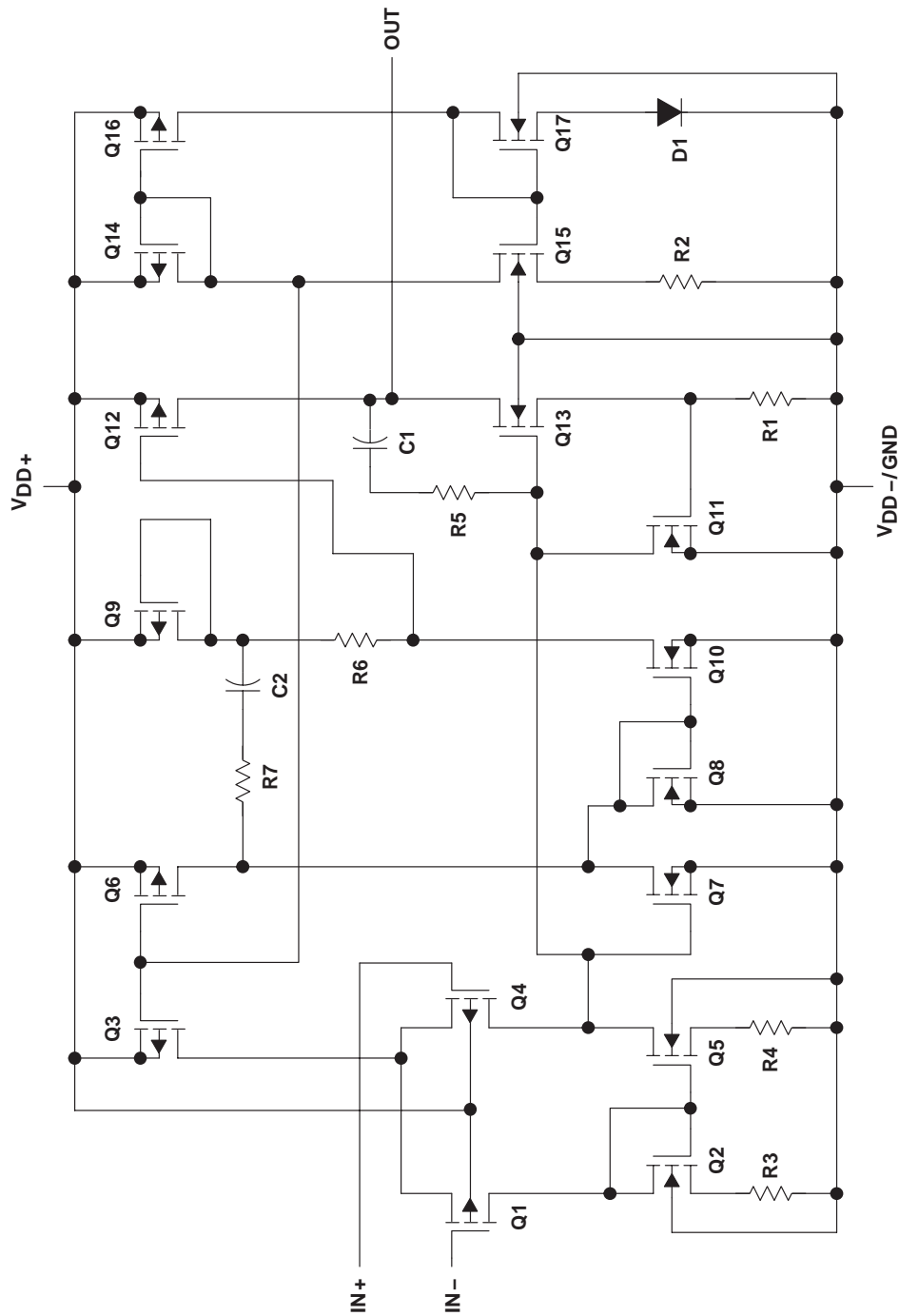
$T_{Jmax} = 150^\circ\text{C}$

TOLERANCES ARE  $\pm 10\%$ .

ALL DIMENSIONS ARE IN MILS.

PIN (2) IS INTERNALLY CONNECTED TO BACKSIDE OF CHIP.

equivalent schematic



COMPONENT COUNT†	
Transistors	23
Diodes	5
Resistors	11
Capacitors	2

† Includes both amplifiers and all ESD, bias, and trim circuitry

# TLV2221, TLV2221Y

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#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

Supply voltage, $V_{DD}$ (see Note 1)	12 V
Differential input voltage, $V_{ID}$ (see Note 2)	$\pm V_{DD}$
Input voltage range, $V_I$ (any input, see Note 1)	-0.3 V to $V_{DD}$
Input current, $I_I$ (each input)	$\pm 5$ mA
Output current, $I_O$	$\pm 50$ mA
Total current into $V_{DD+}$	$\pm 50$ mA
Total current out of $V_{DD-}$	$\pm 50$ mA
Duration of short-circuit current (at or below) 25°C (see Note 3)	unlimited
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range, $T_A$ : TLV2221C	0°C to 70°C
TLV2221I	-40°C to 85°C
Storage temperature range, $T_{stg}$	-65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds: DBV package	260°C

<sup>†</sup> Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltage values, except differential voltages, are with respect to  $V_{DD-}$ .
2. Differential voltages are at the noninverting input with respect to the inverting input. Excessive current flows when input is brought below  $V_{DD-} - 0.3$  V.
3. The output can be shorted to either supply. Temperature and/or supply voltages must be limited to ensure that the maximum dissipation rating is not exceeded.

DISSIPATION RATING TABLE

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$	$T_A = 70^\circ\text{C}$ POWER RATING	$T_A = 85^\circ\text{C}$ POWER RATING
DBV	150 mW	1.2 mW/°C	96 mW	78 mW

#### recommended operating conditions

	TLV2221C		TLV2221I		UNIT
	MIN	MAX	MIN	MAX	
Supply voltage, $V_{DD}$ (see Note 1)	2.7	10	2.7	10	V
Input voltage range, $V_I$	$V_{DD-}$	$V_{DD+} - 1.3$	$V_{DD-}$	$V_{DD+} - 1.3$	V
Common-mode input voltage, $V_{IC}$	$V_{DD-}$	$V_{DD+} - 1.3$	$V_{DD-}$	$V_{DD+} - 1.3$	V
Operating free-air temperature, $T_A$	0	70	-40	85	°C

NOTE 1: All voltage values, except differential voltages, are with respect to  $V_{DD-}$ .

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**electrical characteristics at specified free-air temperature,  $V_{DD} = 3\text{ V}$  (unless otherwise noted)**

PARAMETER		TEST CONDITIONS		T <sub>A</sub> †	TLV2221C			TLV2221I			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
V <sub>IO</sub>	Input offset voltage	V <sub>DD</sub> ± = ±1.5 V, V <sub>IC</sub> = 0, V <sub>O</sub> = 0, R <sub>S</sub> = 50 Ω		Full range	0.62 3			0.62 3			mV
α <sub>VIO</sub>	Temperature coefficient of input offset voltage				1			1			μV/°C
	Input offset voltage long-term drift (see Note 4)			25°C	0.003			0.003			μV/mo
I <sub>IO</sub>	Input offset current			25°C	0.5			0.5			pA
				Full range	150			150			
I <sub>IB</sub>	Input bias current			25°C	1			1			pA
		Full range	150			150					
V <sub>ICR</sub>	Common-mode input voltage range	R <sub>S</sub> = 50 Ω,  V <sub>IO</sub>   ≤ 5 mV		25°C	0 to 2	−0.3 to 2.2		0 to 2	−0.3 to 2.2	V	
				Full range	0 to 1.7			0 to 1.7			
V <sub>OH</sub>	High-level output voltage	I <sub>OH</sub> = −100 μA		25°C	2.97			2.97			V
		I <sub>OH</sub> = −400 μA		25°C	2.88			2.88			
				Full range	2.5			2.5			
V <sub>OL</sub>	Low-level output voltage	V <sub>IC</sub> = 1.5 V, I <sub>OL</sub> = 50 μA		25°C	15			15			mV
		V <sub>IC</sub> = 1.5 V, I <sub>OL</sub> = 500 μA		25°C	150			150			
				Full range	500			500			
A <sub>VD</sub>	Large-signal differential voltage amplification	V <sub>IC</sub> = 1.5 V, V <sub>O</sub> = 1 V to 2 V	R <sub>L</sub> = 2 kΩ‡	25°C	2	3		2	3	V/mV	
			R <sub>L</sub> = 1 MΩ‡	Full range	1			1			
					25°C	250			250		
r <sub>id</sub>	Differential input resistance			25°C	10 <sup>12</sup>			10 <sup>12</sup>			Ω
r <sub>ic</sub>	Common-mode input resistance			25°C	10 <sup>12</sup>			10 <sup>12</sup>			Ω
c <sub>ic</sub>	Common-mode input capacitance	f = 10 kHz		25°C	6			6			pF
z <sub>O</sub>	Closed-loop output impedance	f = 10 kHz, A <sub>V</sub> = 10		25°C	90			90			Ω
CMRR	Common-mode rejection ratio	V <sub>IC</sub> = 0 to 1.7 V, V <sub>O</sub> = 1.5 V, R <sub>S</sub> = 50 Ω		25°C	70	82		70	82	dB	
				Full range	65			65			
k <sub>SVR</sub>	Supply voltage rejection ratio (ΔV <sub>DD</sub> /ΔV <sub>IO</sub> )	V <sub>DD</sub> = 2.7 V to 8 V, V <sub>IC</sub> = V <sub>DD</sub> /2, No load		25°C	80	95		80	95	dB	
				Full range	80			80			
I <sub>DD</sub>	Supply current	V <sub>O</sub> = 1.5 V, No load		25°C	100	150		100	150	μA	
				Full range	200			200			

$^\dagger$  Full range for the TLV2221C is 0°C to 70°C. Full range for the TLV2221I is -40°C to 85°C.

$^\ddagger$  Referenced to 1.5 V

NOTE 4: Typical values are based on the input offset voltage shift observed through 500 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.

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operating characteristics at specified free-air temperature,  $V_{DD} = 3\text{ V}$

PARAMETER		TEST CONDITIONS	$T_A$ †	TLV2221C			TLV2221I			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
SR	Slew rate at unity gain	$V_O = 1.1\text{ V to }1.9\text{ V}, R_L = 2\text{ k}\Omega^\ddagger, C_L = 100\text{ pF}^\ddagger$	25°C	0.1	0.18		0.1	0.18		V/ $\mu\text{s}$
			Full range	0.05			0.05			
$V_n$	Equivalent input noise voltage	$f = 10\text{ Hz}$	25°C		120			120		nV/ $\sqrt{\text{Hz}}$
		$f = 1\text{ kHz}$	25°C		20			20		
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$	25°C		680			680		nV
		$f = 0.1\text{ Hz to }10\text{ Hz}$	25°C		860			860		
$I_n$	Equivalent input noise current		25°C		0.6			0.6		fA/ $\sqrt{\text{Hz}}$
THD+N	Total harmonic distortion plus noise	$V_O = 1\text{ V to }2\text{ V}, f = 20\text{ kHz}, R_L = 2\text{ k}\Omega^\ddagger$	25°C		$A_V = 1$			2.52%		
					$A_V = 10$			7.01%		
		$V_O = 1\text{ V to }2\text{ V}, f = 20\text{ kHz}, R_L = 2\text{ k}\Omega^\S$	25°C		$A_V = 1$			0.076%		
					$A_V = 10$			0.147%		
	Gain-bandwidth product	$f = 1\text{ kHz}, R_L = 2\text{ k}\Omega^\ddagger, C_L = 100\text{ pF}^\ddagger$	25°C		480			480		kHz
$B_{OM}$	Maximum output-swing bandwidth	$V_{O(PP)} = 1\text{ V}, R_L = 2\text{ k}\Omega^\ddagger, A_V = 1, C_L = 100\text{ pF}^\ddagger$	25°C		30			30		kHz
$t_s$	Settling time	$A_V = -1, \text{Step} = 1\text{ V to }2\text{ V}, R_L = 2\text{ k}\Omega^\ddagger, C_L = 100\text{ pF}^\ddagger$	25°C		4.5			4.5		$\mu\text{s}$
			25°C		6.8			6.8		$\mu\text{s}$
$\phi_m$	Phase margin at unity gain	$R_L = 2\text{ k}\Omega^\ddagger, C_L = 100\text{ pF}^\ddagger$	25°C		51°			51°		
	Gain margin		25°C		12			12		dB

† Full range is –40°C to 85°C.

‡ Referenced to 1.5 V

§ Referenced to 0 V

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**electrical characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$  (unless otherwise noted)**

PARAMETER		TEST CONDITIONS		T <sub>A</sub> †	TLV2221C			TLV2221I			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
V <sub>IO</sub>	Input offset voltage	V <sub>DD±</sub> = ±2.5 V, V <sub>IC</sub> = 0, V <sub>O</sub> = 0, R <sub>S</sub> = 50 Ω		Full range	0.61 3			0.61 3			mV
α <sub>VIO</sub>	Temperature coefficient of input offset voltage				1			1			μV/°C
	Input offset voltage long-term drift (see Note 4)			25°C	0.003			0.003			μV/mo
I <sub>IO</sub>	Input offset current			25°C	0.5			0.5			pA
				Full range	150			150			
I <sub>IB</sub>	Input bias current			25°C	1			1			pA
		Full range	150			150					
V <sub>ICR</sub>	Common-mode input voltage range	R <sub>S</sub> = 50 Ω,  V <sub>IO</sub>   ≤ 5 mV		25°C	0 to 4	–0.3 to 4.2		0 to 4	–0.3 to 4.2	V	
				Full range	0 to 3.5		0 to 3.5				
V <sub>OH</sub>	High-level output voltage	I <sub>OH</sub> = –500 μA I <sub>OH</sub> = –1 mA		25°C	4.75	4.88		4.75	4.88	V	
					4.5	4.76		4.5	4.76		
V <sub>OL</sub>	Low-level output voltage	V <sub>IC</sub> = 2.5 V, I <sub>OL</sub> = 50 μA		25°C	12			12			mV
		V <sub>IC</sub> = 2.5 V, I <sub>OL</sub> = 500 μA		25°C	120			120			
				Full range	500			500			
A <sub>VD</sub>	Large-signal differential voltage amplification	V <sub>IC</sub> = 2.5 V, V <sub>O</sub> = 1 V to 4 V	R <sub>L</sub> = 2 kΩ‡	25°C	3	5		3	5	V/mV	
				Full range	1		1				
			R <sub>L</sub> = 1 MΩ‡	25°C	800			800			
r <sub>id</sub>	Differential input resistance			25°C	10 <sup>12</sup>			10 <sup>12</sup>			Ω
r <sub>ic</sub>	Common-mode input resistance			25°C	10 <sup>12</sup>			10 <sup>12</sup>			Ω
c <sub>ic</sub>	Common-mode input capacitance	f = 10 kHz		25°C	6			6			pF
z <sub>O</sub>	Closed-loop output impedance	f = 10 kHz, A <sub>V</sub> = 10		25°C	70			70			Ω
CMRR	Common-mode rejection ratio	V <sub>IC</sub> = 0 to 2.7 V, V <sub>O</sub> = 1.5 V, R <sub>S</sub> = 50 Ω		25°C	70	85		70	85	dB	
				Full range	65			65			
kSVR	Supply voltage rejection ratio (ΔV <sub>DD</sub> /ΔV <sub>IO</sub> )	V <sub>DD</sub> = 4.4 V to 8 V, V <sub>IC</sub> = V <sub>DD</sub> /2, No load		25°C	80	95		80	95	dB	
				Full range	80			80			
I <sub>DD</sub>	Supply current	V <sub>O</sub> = 2.5 V, No load		25°C	110 150			110 150			μA
				Full range	200			200			

† Full range for the TLV2221C is 0°C to 70°C. Full range for the TLV2221I is –40°C to 85°C.

‡ Referenced to 2.5 V

NOTE 5: Typical values are based on the input offset voltage shift observed through 500 hours of operating life test at  $T_A = 150^\circ\text{C}$  extrapolated to  $T_A = 25^\circ\text{C}$  using the Arrhenius equation and assuming an activation energy of 0.96 eV.

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operating characteristics at specified free-air temperature,  $V_{DD} = 5\text{ V}$

PARAMETER		TEST CONDITIONS		T <sub>A</sub> <sup>†</sup>	TLV2221C			TLV2221I			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR	Slew rate at unity gain	V <sub>O</sub> = 1.5 V to 3.5 V, R <sub>L</sub> = 2 kΩ <sup>‡</sup> , C <sub>L</sub> = 100 pF <sup>‡</sup>		25°C	0.1	0.18		0.1	0.18		V/μs
				Full range	0.05			0.05			
V <sub>n</sub>	Equivalent input noise voltage	f = 10 Hz		25°C	90			90			nV/√Hz
		f = 1 kHz		25°C	19			19			
V <sub>N(PP)</sub>	Peak-to-peak equivalent input noise voltage	f = 0.1 Hz to 1 Hz		25°C	800			800			nV
		f = 0.1 Hz to 10 Hz		25°C	960			960			
I <sub>n</sub>	Equivalent input noise current			25°C	0.6			0.6			fA/√Hz
THD+N	Total harmonic distortion plus noise	V <sub>O</sub> = 1.5 V to 3.5 V, f = 20 kHz, R <sub>L</sub> = 2 kΩ <sup>‡</sup>	A <sub>V</sub> = 1	25°C	2.45%			2.45%			
			A <sub>V</sub> = 10		5.54%			5.54%			
		V <sub>O</sub> = 1.5 V to 3.5 V, f = 20 kHz, R <sub>L</sub> = 2 kΩ <sup>§</sup>	A <sub>V</sub> = 1	25°C	0.142%			0.142%			
			A <sub>V</sub> = 10		0.257%			0.257%			
	Gain-bandwidth product	f = 1 kHz, R <sub>L</sub> = 2 kΩ <sup>‡</sup> , C <sub>L</sub> = 100 pF <sup>‡</sup>		25°C	510			510			kHz
B <sub>OM</sub>	Maximum output-swing bandwidth	V <sub>O(PP)</sub> = 1 V, R <sub>L</sub> = 2 kΩ <sup>‡</sup> ,		25°C	40			40			kHz
t <sub>s</sub>	Settling time	A <sub>V</sub> = −1, Step = 1.5 V to 3.5 V, R <sub>L</sub> = 2 kΩ <sup>‡</sup> , C <sub>L</sub> = 100 pF <sup>‡</sup>	To 0.1%	25°C	6.8			6.8			μs
			To 0.01%	25°C	9.2			9.2			
ϕ <sub>m</sub>	Phase margin at unity gain	R <sub>L</sub> = 2 kΩ <sup>‡</sup> , C <sub>L</sub> = 100 pF <sup>‡</sup>		25°C	52°			52°			
	Gain margin			25°C	12			12			dB

† Full range is –40°C to 85°C.

‡ Referenced to 2.5 V

§ Referenced to 0 V

**electrical characteristics at  $V_{DD} = 3\text{ V}$ ,  $T_A = 25^\circ\text{C}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	TLV2221Y			UNIT
		MIN	TYP	MAX	
$V_{IO}$ Input offset voltage	$V_{DD} \pm \pm 1.5\text{ V}$ , $R_S = 50\ \Omega$ $V_{IC} = 0$ , $V_O = 0$ ,		620		$\mu\text{V}$
$I_{IO}$ Input offset current			0.5		$\text{pA}$
$I_{IB}$ Input bias current			1		$\text{pA}$
$V_{ICR}$ Common-mode input voltage range	$ V_{IO}  \leq 5\text{ mV}$ , $R_S = 50\ \Omega$		–0.3 to 2.2		$\text{V}$
$V_{OH}$ High-level output voltage	$I_{OH} = -100\ \mu\text{A}$		2.97		$\text{V}$
$V_{OL}$ Low-level output voltage	$V_{IC} = 1.5\text{ V}$ , $I_{OL} = 50\ \mu\text{A}$		15		$\text{mV}$
	$V_{IC} = 1.5\text{ V}$ , $I_{OL} = 500\ \mu\text{A}$		150		
$A_{VD}$ Large-signal differential voltage amplification	$V_O = 1\text{ V to } 2\text{ V}$	$R_L = 2\text{ k}\Omega^\dagger$	3		$\text{V/mV}$
		$R_L = 1\text{ M}\Omega^\dagger$	250		
$r_{id}$ Differential input resistance			$10^{12}$		$\Omega$
$r_{ic}$ Common-mode input resistance			$10^{12}$		$\Omega$
$c_{ic}$ Common-mode input capacitance	$f = 10\text{ kHz}$		6		$\text{pF}$
$z_o$ Closed-loop output impedance	$f = 10\text{ kHz}$ , $A_V = 10$		90		$\Omega$
CMRR Common-mode rejection ratio	$V_{IC} = 0\text{ to } 1.7\text{ V}$ , $V_O = 0$ , $R_S = 50\ \Omega$		82		$\text{dB}$
$k_{SVR}$ Supply voltage rejection ratio ( $\Delta V_{DD}/\Delta V_{IO}$ )	$V_{DD} = 2.7\text{ V to } 8\text{ V}$ , $V_{IC} = 0$ ,      No load		95		$\text{dB}$
$I_{DD}$ Supply current	$V_O = 0$ ,      No load		100		$\mu\text{A}$

$^\dagger$  Referenced to 1.5 V

**electrical characteristics at  $V_{DD} = 5\text{ V}$ ,  $T_A = 25^\circ\text{C}$  (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	TLV2221Y			UNIT
		MIN	TYP	MAX	
$V_{IO}$ Input offset voltage	$V_{DD} \pm \pm 1.5\text{ V}$ , $R_S = 50\ \Omega$ $V_{IC} = 0$ , $V_O = 0$ ,		610		$\mu\text{V}$
$I_{IO}$ Input offset current			0.5		$\text{pA}$
$I_{IB}$ Input bias current			1		$\text{pA}$
$V_{ICR}$ Common-mode input voltage range	$ V_{IO}  \leq 5\text{ mV}$ , $R_S = 50\ \Omega$		–0.3 to 4.2		$\text{V}$
$V_{OH}$ High-level output voltage	$I_{OH} = -500\ \mu\text{A}$		4.88		$\text{V}$
$V_{OL}$ Low-level output voltage	$V_{IC} = 2.5\text{ V}$ , $I_{OL} = 50\ \mu\text{A}$		12		$\text{mV}$
	$V_{IC} = 2.5\text{ V}$ , $I_{OL} = 500\ \mu\text{A}$		120		
$A_{VD}$ Large-signal differential voltage amplification	$V_O = 1\text{ V to } 4\text{ V}$	$R_L = 2\text{ k}\Omega^\dagger$	5		$\text{V/mV}$
		$R_L = 1\text{ M}\Omega^\dagger$	800		
$r_{id}$ Differential input resistance			$10^{12}$		$\Omega$
$r_{ic}$ Common-mode input resistance			$10^{12}$		$\Omega$
$c_{ic}$ Common-mode input capacitance	$f = 10\text{ kHz}$		6		$\text{pF}$
$z_o$ Closed-loop output impedance	$f = 10\text{ kHz}$ , $A_V = 10$		70		$\Omega$
CMRR Common-mode rejection ratio	$V_{IC} = 0\text{ to } 1.7\text{ V}$ , $V_O = 0$ , $R_S = 50\ \Omega$		85		$\text{dB}$
$k_{SVR}$ Supply voltage rejection ratio ( $\Delta V_{DD}/\Delta V_{IO}$ )	$V_{DD} = 2.7\text{ V to } 8\text{ V}$ , $V_{IC} = 0$ ,      No load		95		$\text{dB}$
$I_{DD}$ Supply current	$V_O = 0$ ,      No load		110		$\mu\text{A}$

$^\dagger$  Referenced to 2.5 V

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**TYPICAL CHARACTERISTICS**

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## TYPICAL CHARACTERISTICS

**DISTRIBUTION OF TLV2211  
INPUT OFFSET VOLTAGE**

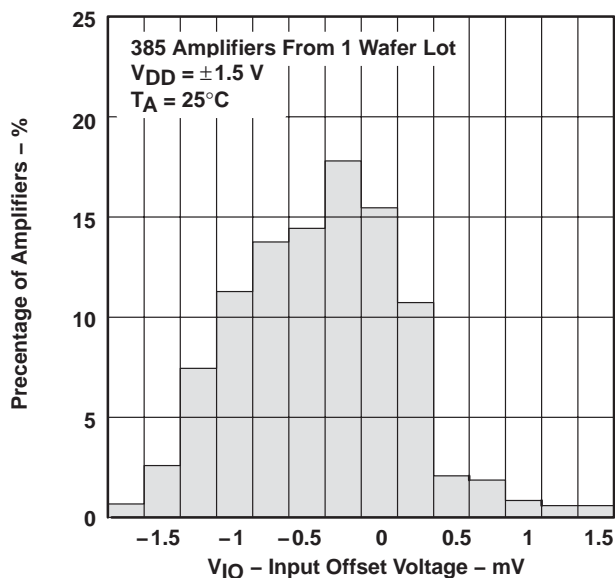


Figure 2

**DISTRIBUTION OF TLV2211  
INPUT OFFSET VOLTAGE**

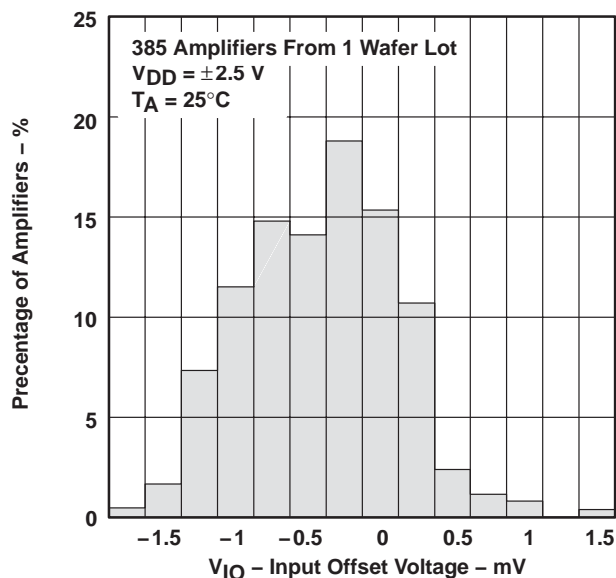


Figure 3

**INPUT OFFSET VOLTAGE†  
vs  
COMMON-MODE INPUT VOLTAGE**

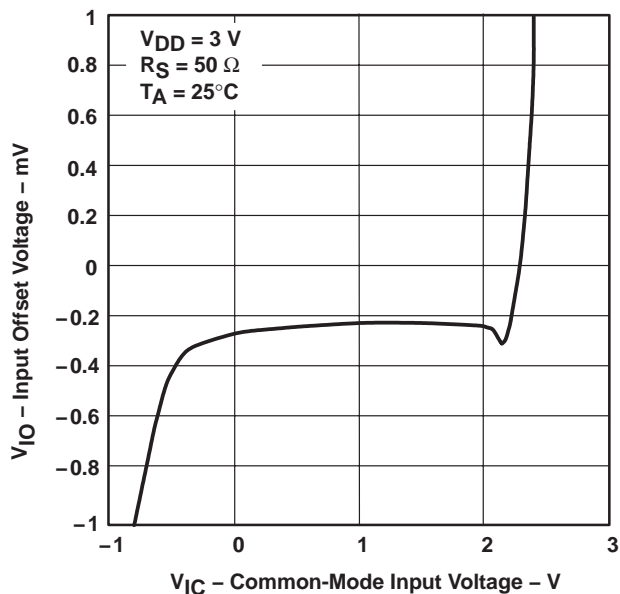


Figure 4

**INPUT OFFSET VOLTAGE†  
vs  
COMMON-MODE INPUT VOLTAGE**

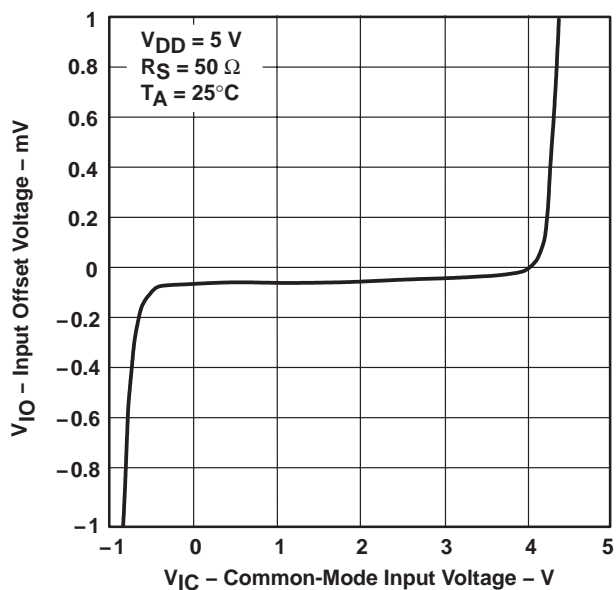


Figure 5

† For all curves where  $V_{DD} = 5 \text{ V}$ , all loads are referenced to 2.5 V. For all curves where  $V_{DD} = 3 \text{ V}$ , all loads are referenced to 1.5 V.

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#### TYPICAL CHARACTERISTICS

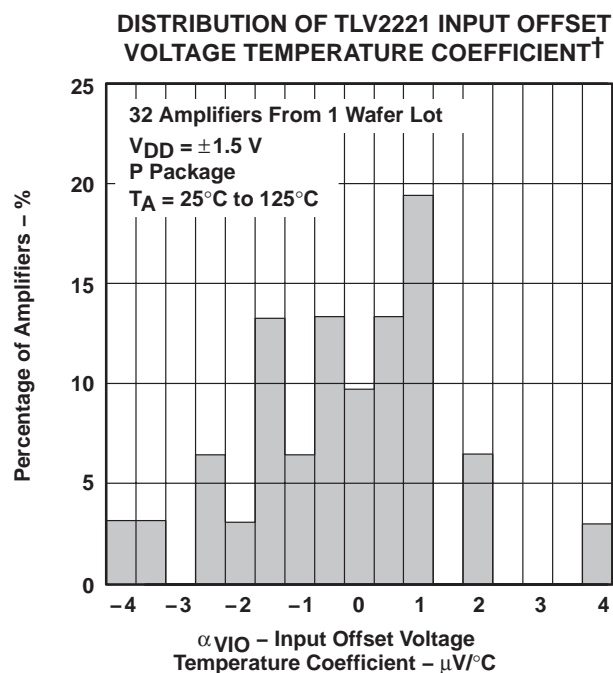


Figure 6

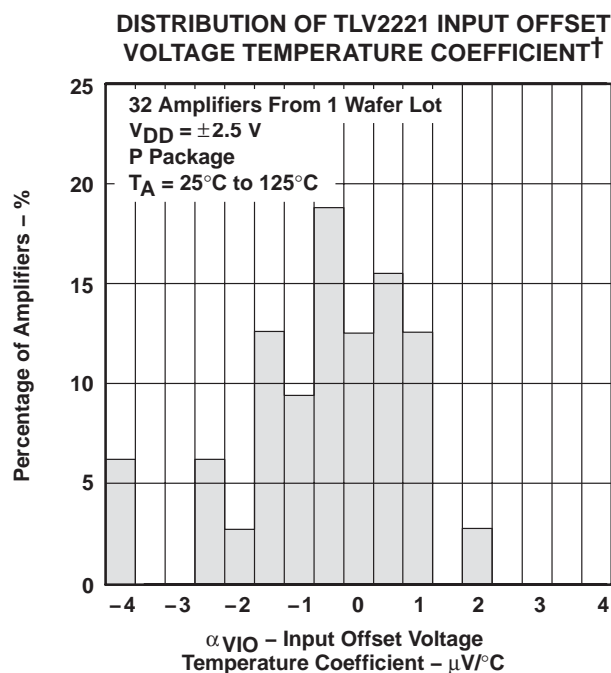


Figure 7

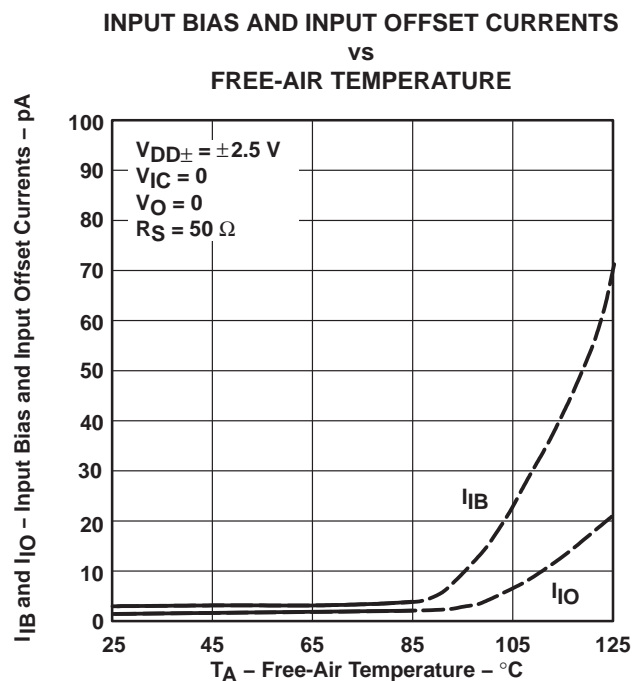


Figure 8

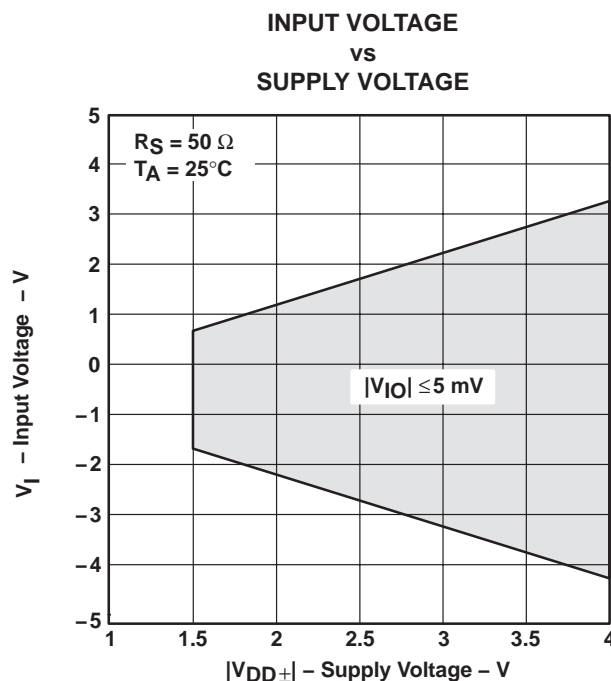


Figure 9

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

## TYPICAL CHARACTERISTICS

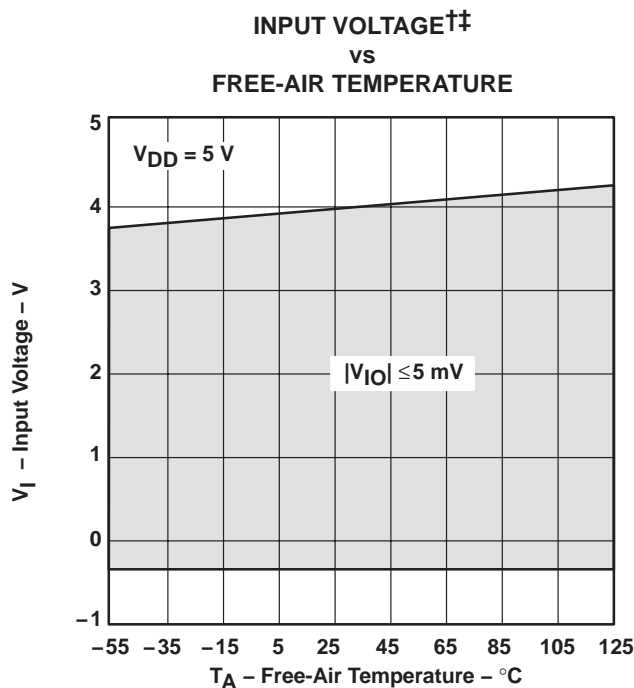


Figure 10

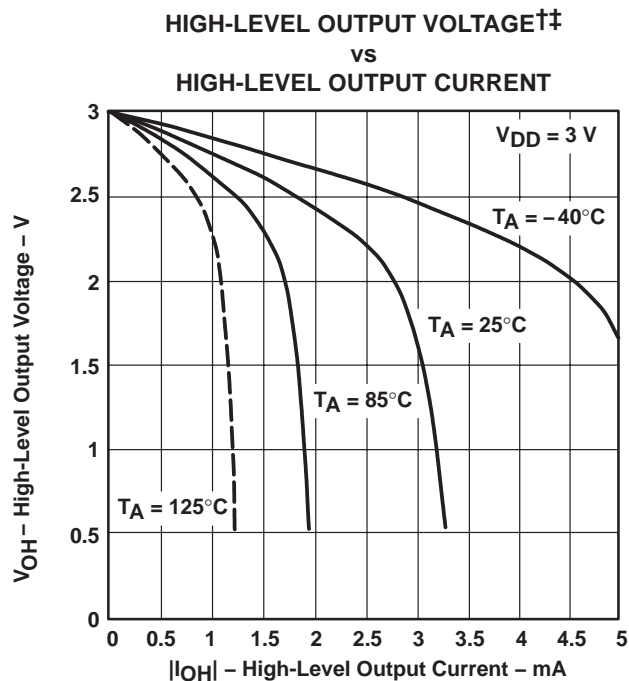


Figure 11

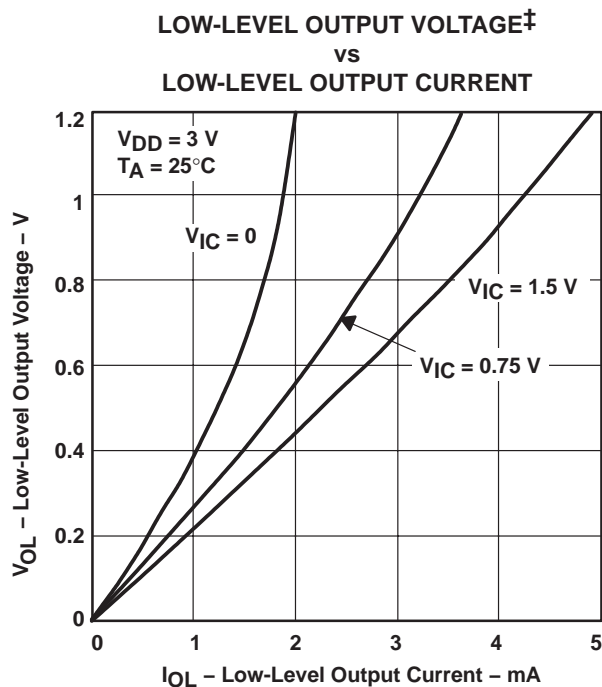


Figure 12

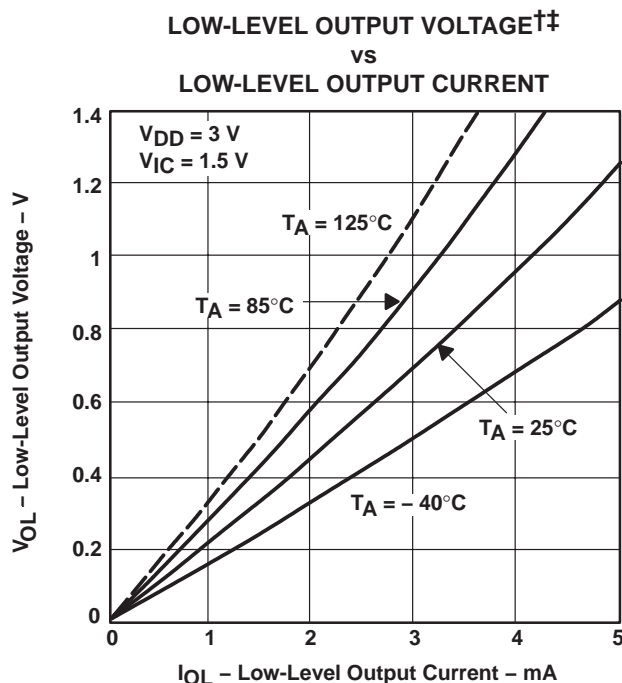


Figure 13

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

†† For all curves where  $V_{DD} = 5 \text{ V}$ , all loads are referenced to 2.5 V. For all curves where  $V_{DD} = 3 \text{ V}$ , all loads are referenced to 1.5 V.

# TLV2221, TLV2221Y

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#### TYPICAL CHARACTERISTICS

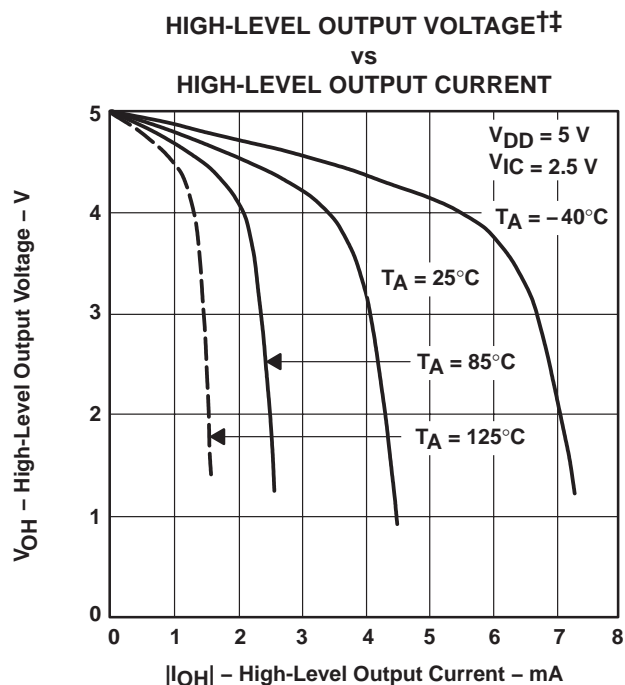


Figure 14

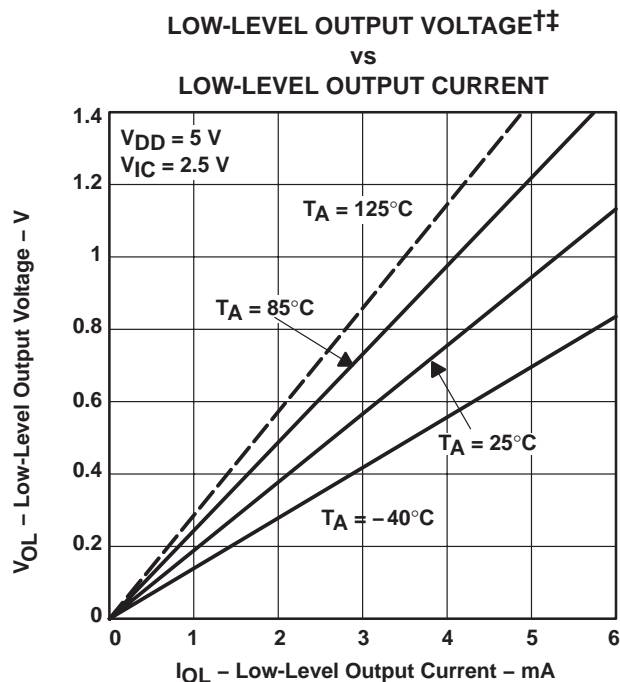


Figure 15

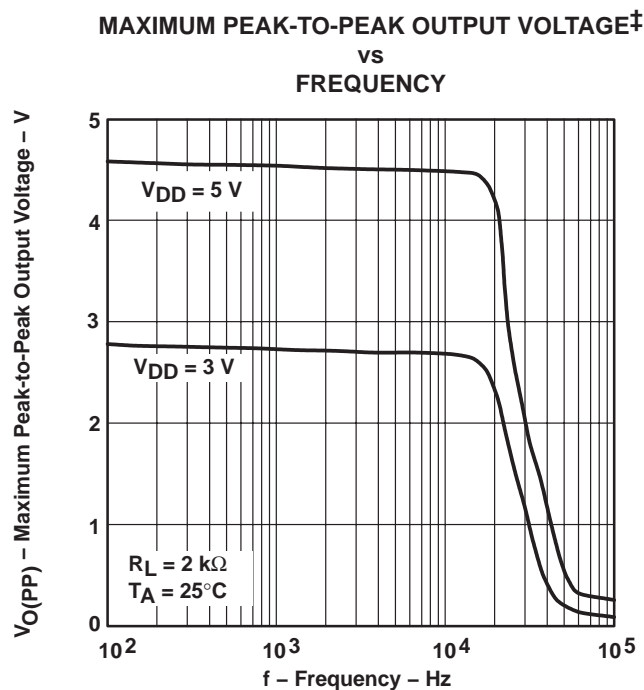


Figure 16

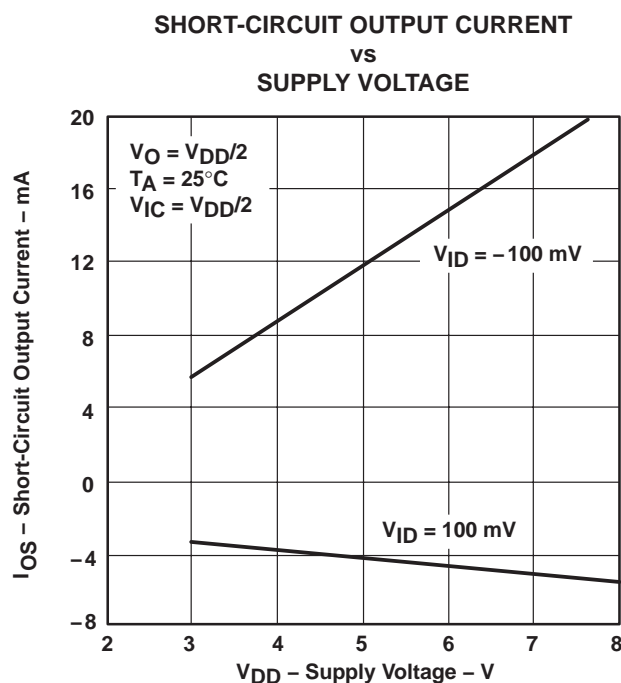
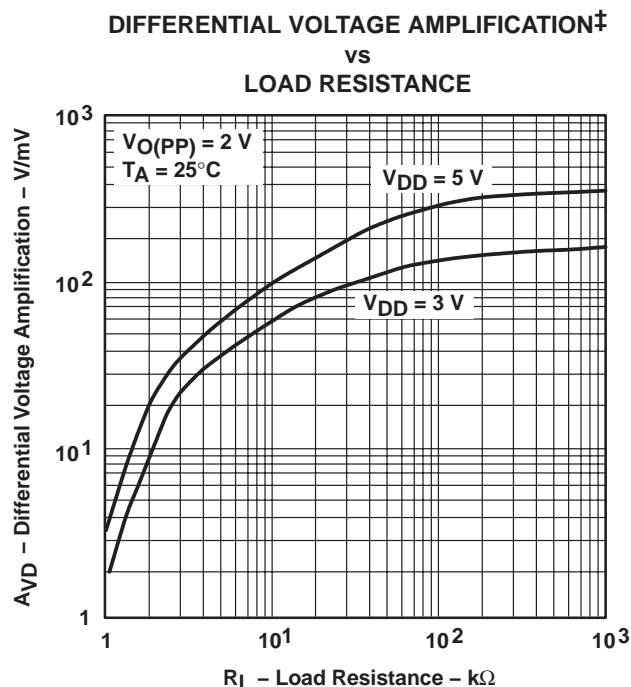
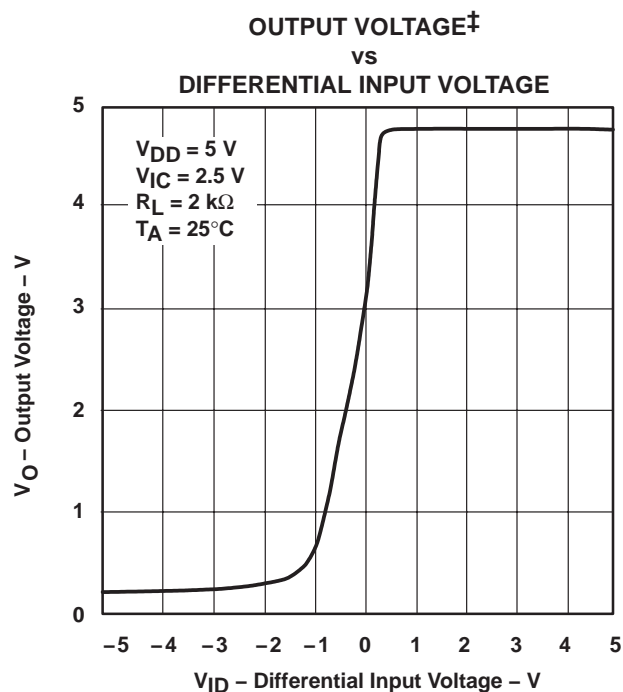
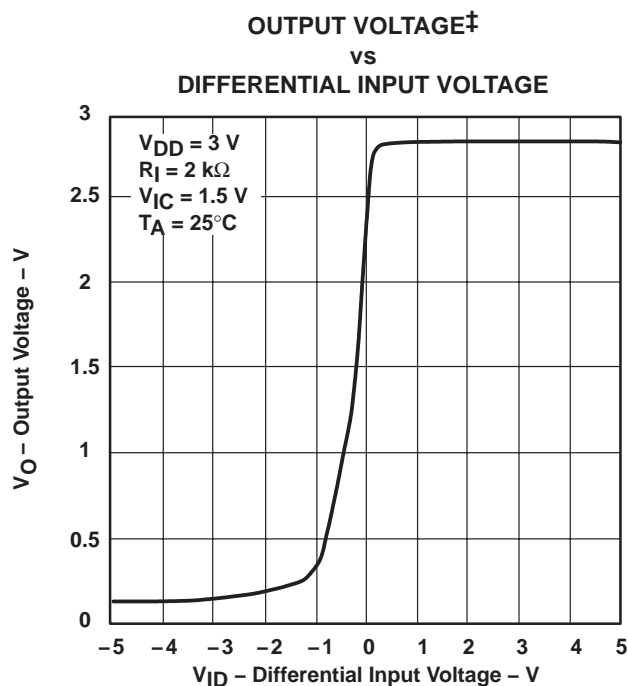
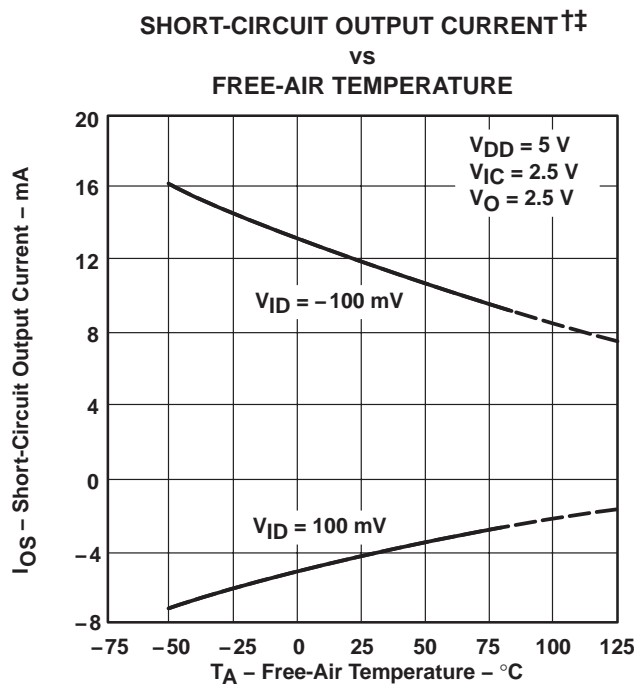


Figure 17

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

‡ For all curves where  $V_{DD} = 5\text{ V}$ , all loads are referenced to 2.5 V. For all curves where  $V_{DD} = 3\text{ V}$ , all loads are referenced to 1.5 V.

## TYPICAL CHARACTERISTICS



† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

‡ For all curves where  $V_{DD} = 5\text{ V}$ , all loads are referenced to 2.5 V. For all curves where  $V_{DD} = 3\text{ V}$ , all loads are referenced to 1.5 V.

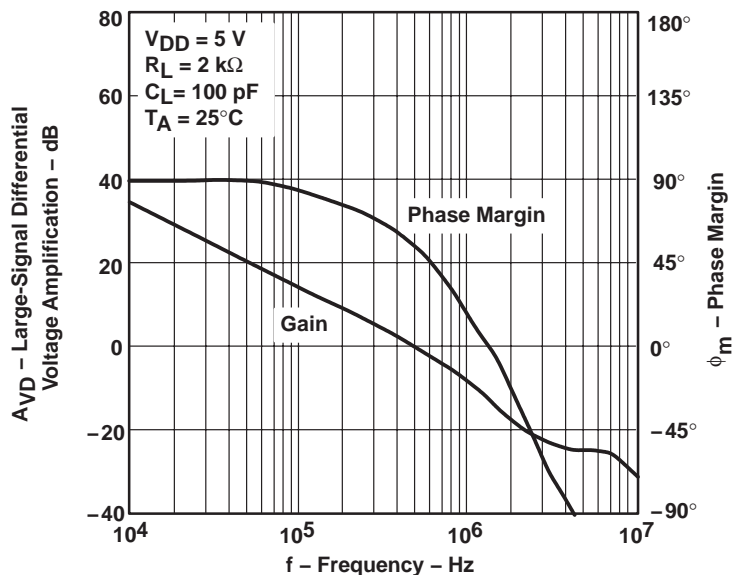
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**TYPICAL CHARACTERISTICS**

**LARGE-SIGNAL DIFFERENTIAL VOLTAGE†  
AMPLIFICATION AND PHASE MARGIN**

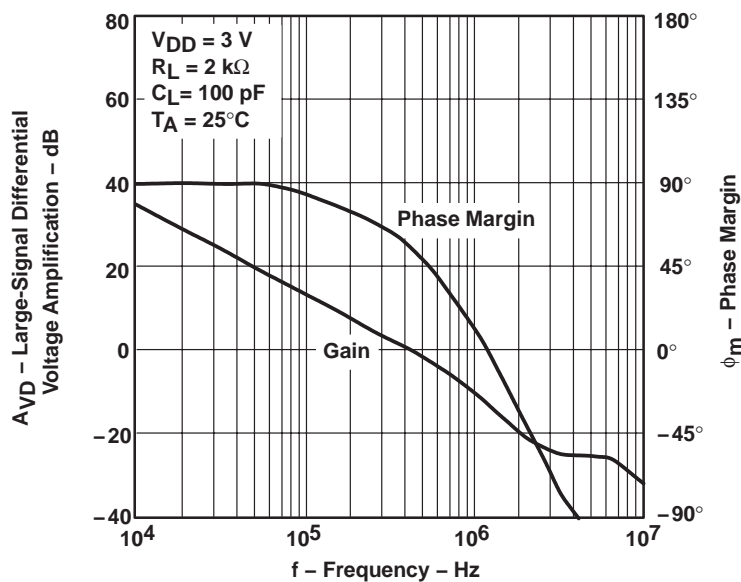
**VS  
FREQUENCY**



**Figure 22**

**LARGE-SIGNAL DIFFERENTIAL VOLTAGE  
AMPLIFICATION AND PHASE MARGIN†**

**VS  
FREQUENCY**



**Figure 23**

† For all curves where  $V_{DD} = 5\text{ V}$ , all loads are referenced to 2.5 V. For all curves where  $V_{DD} = 3\text{ V}$ , all loads are referenced to 1.5 V.

## TYPICAL CHARACTERISTICS

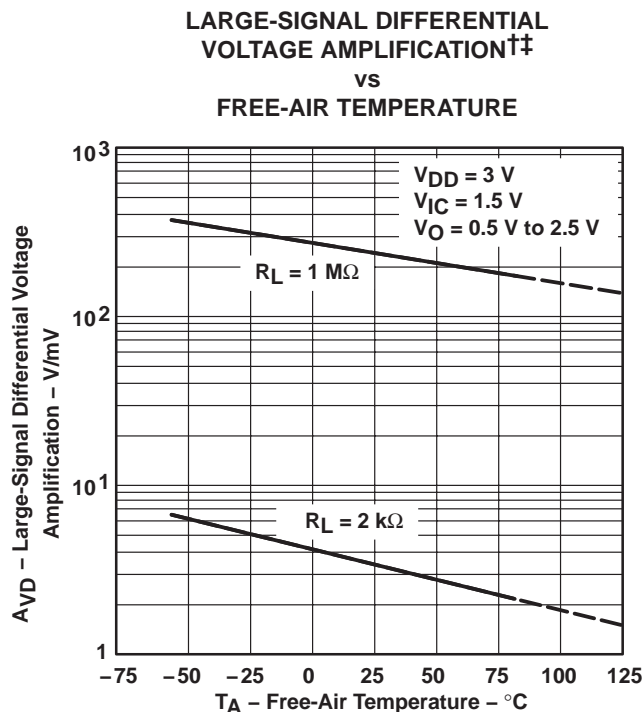


Figure 24

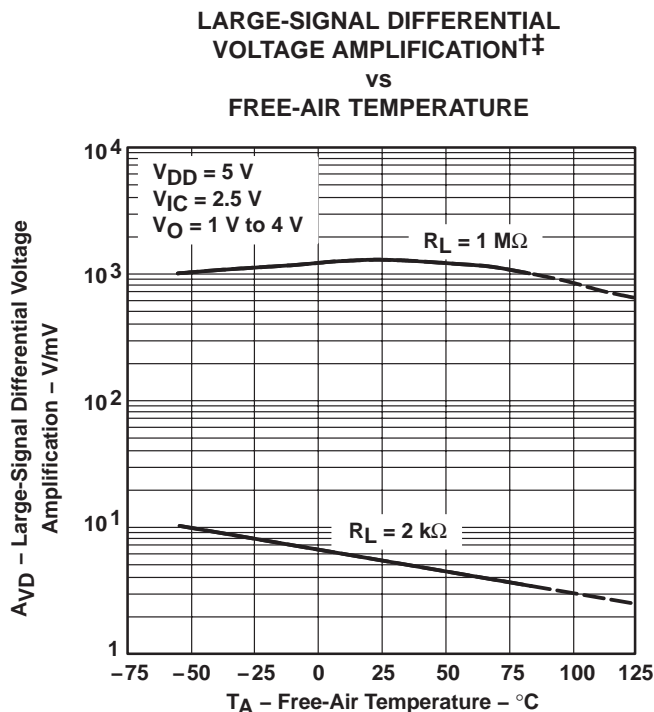


Figure 25

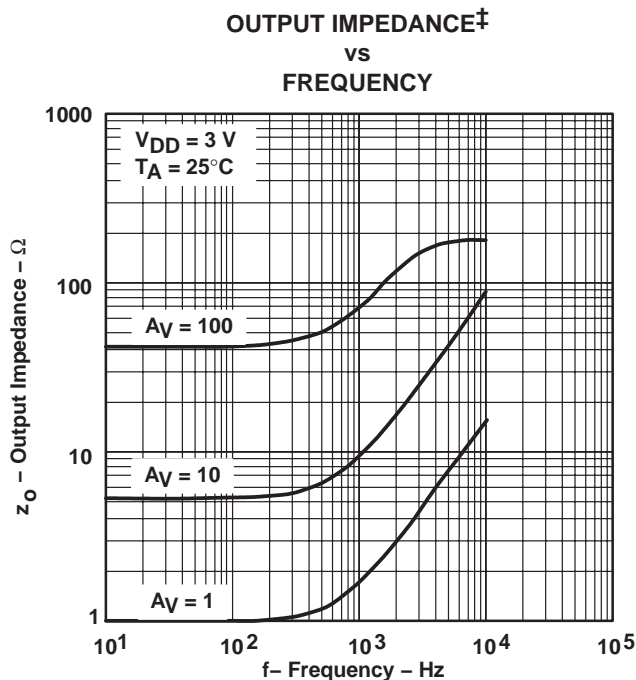


Figure 26

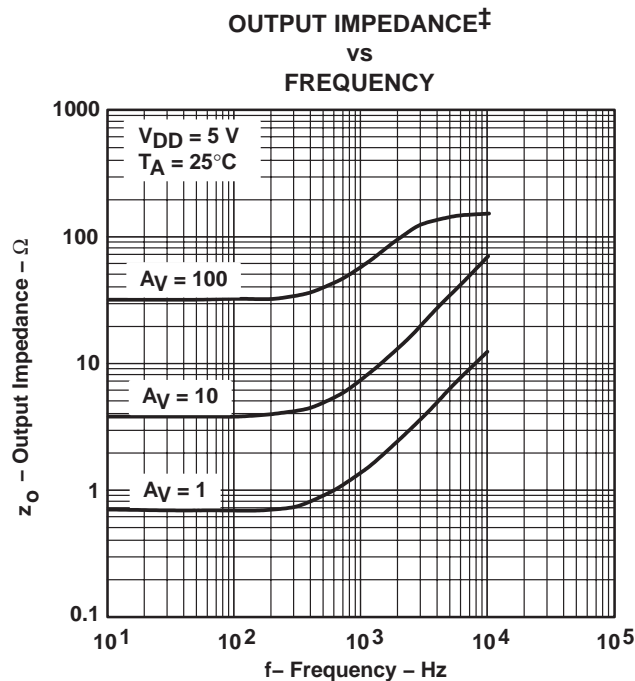


Figure 27

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

‡ For all curves where  $V_{DD} = 5\text{ V}$ , all loads are referenced to 2.5 V. For all curves where  $V_{DD} = 3\text{ V}$ , all loads are referenced to 1.5 V.

## TYPICAL CHARACTERISTICS

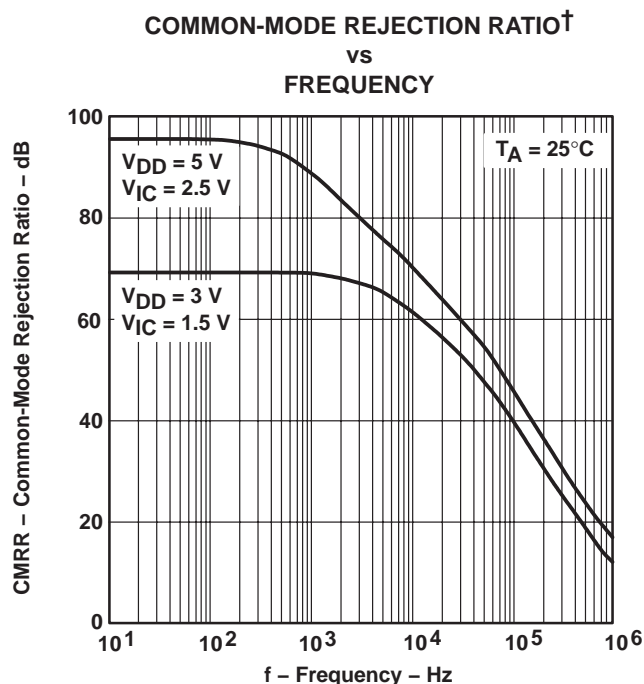


Figure 28

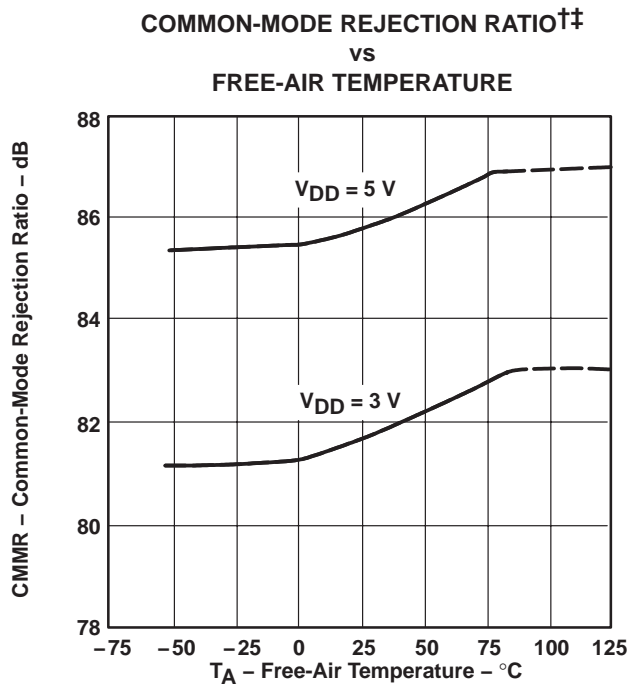


Figure 29

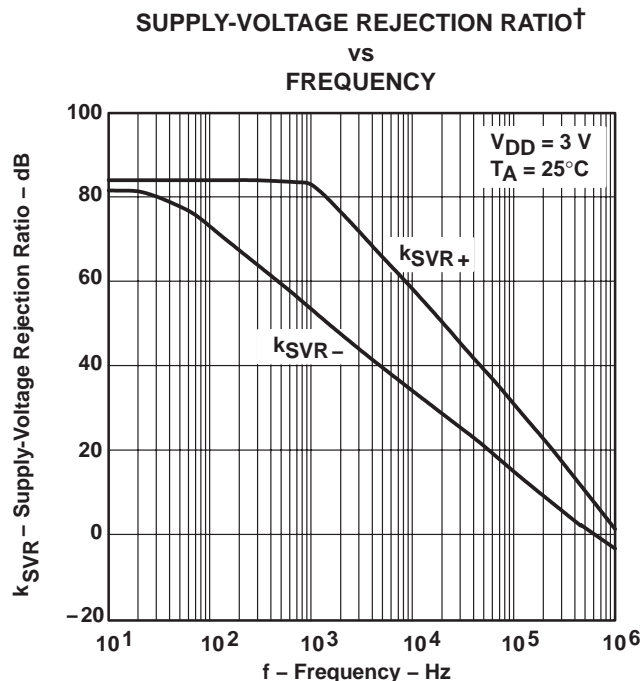


Figure 30

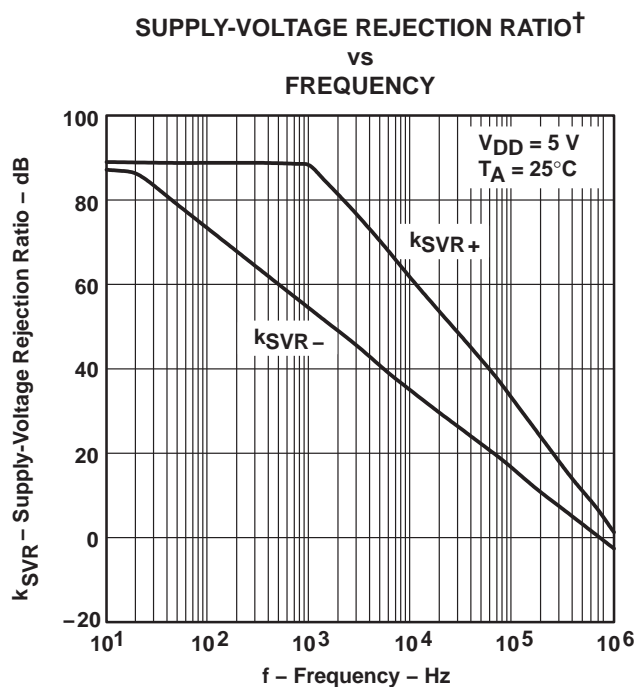


Figure 31

† For all curves where  $V_{DD} = 5\text{ V}$ , all loads are referenced to 2.5 V. For all curves where  $V_{DD} = 3\text{ V}$ , all loads are referenced to 1.5 V.

‡ Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

## TYPICAL CHARACTERISTICS

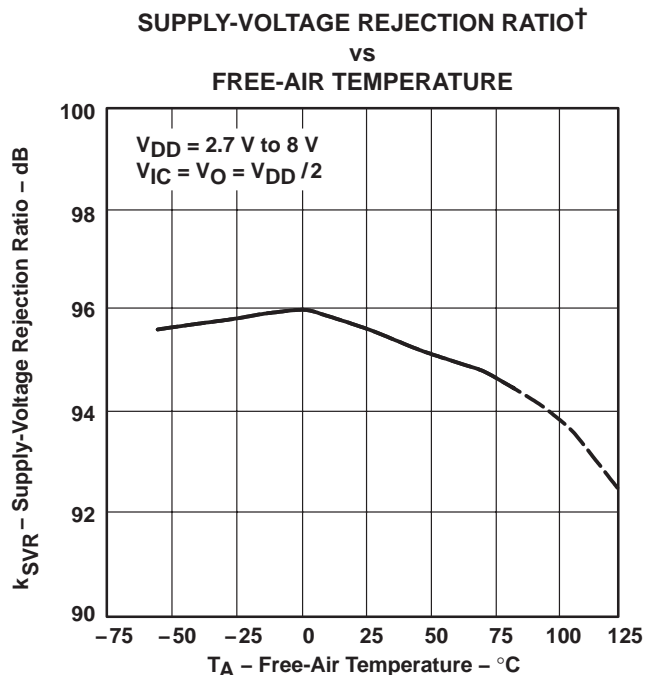


Figure 32

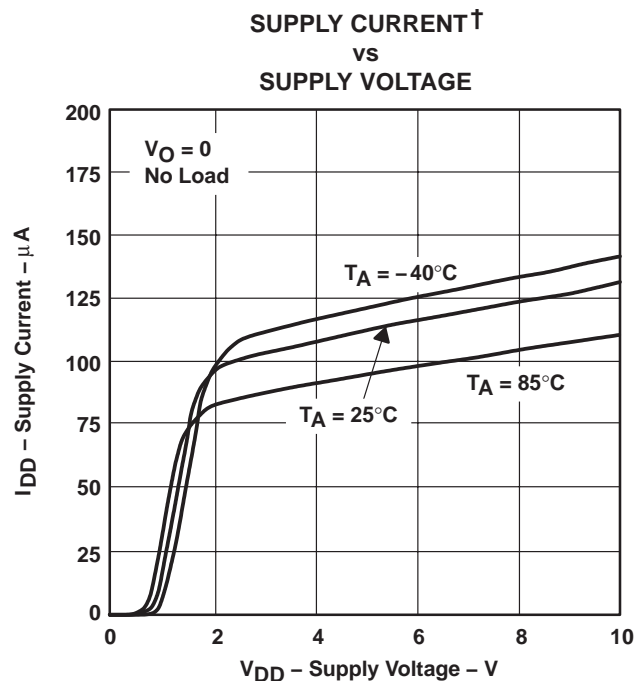


Figure 33

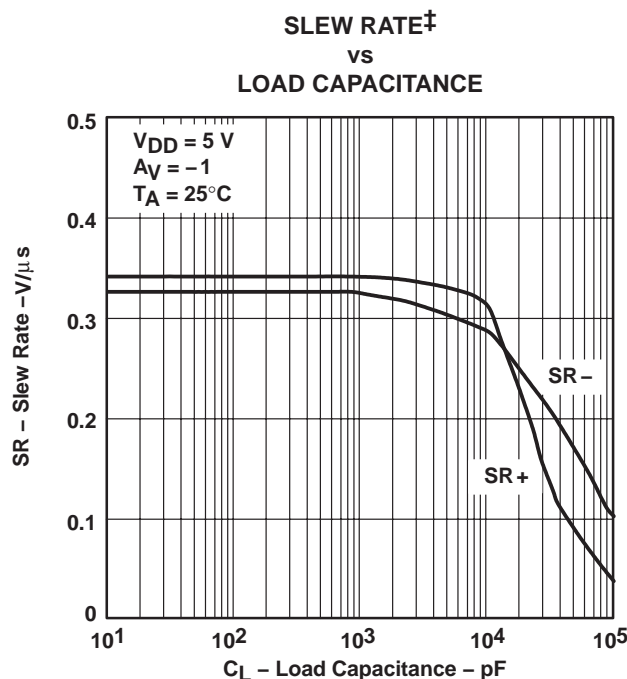


Figure 34

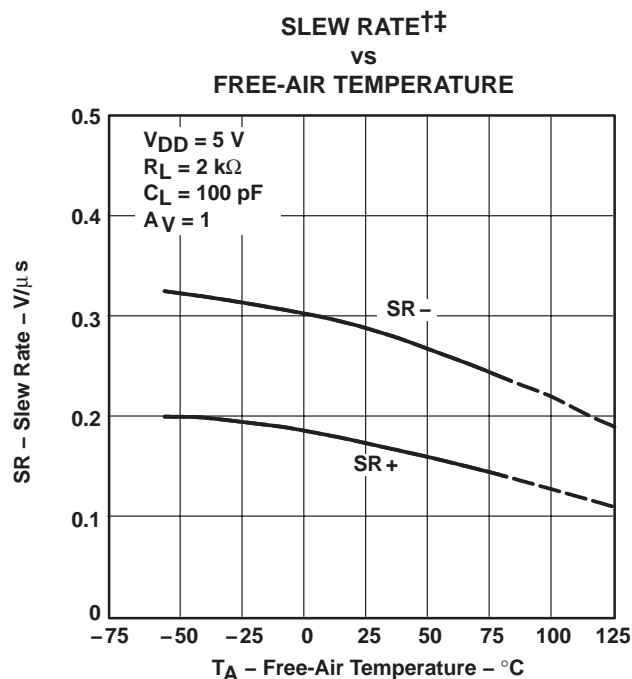


Figure 35

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

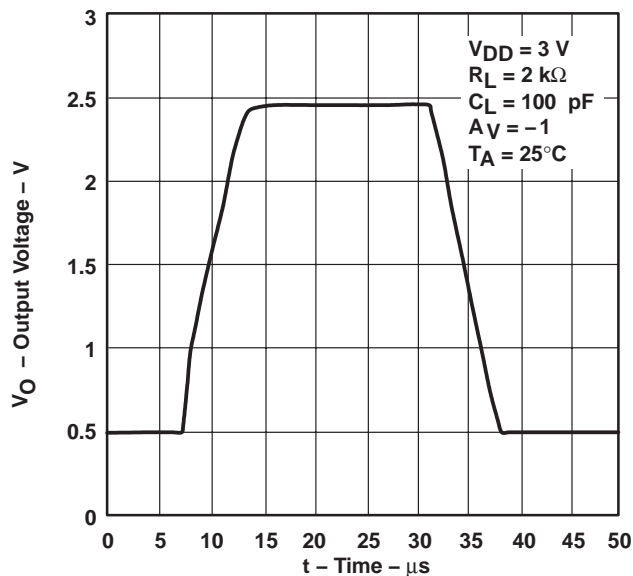
‡ For all curves where  $V_{DD} = 5 \text{ V}$ , all loads are referenced to 2.5 V. For all curves where  $V_{DD} = 3 \text{ V}$ , all loads are referenced to 1.5 V.

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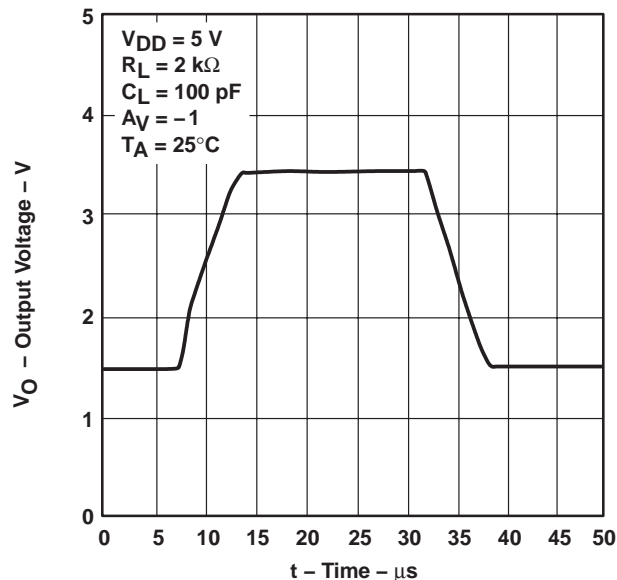
**TYPICAL CHARACTERISTICS**

**INVERTING LARGE-SIGNAL PULSE RESPONSE†**



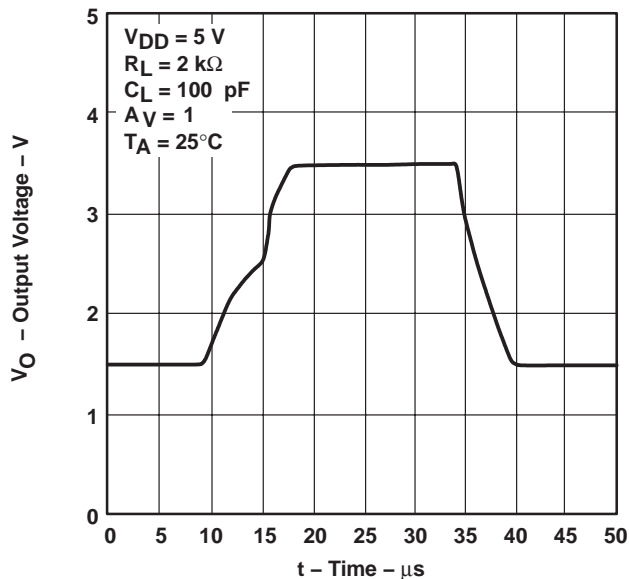
**Figure 36**

**INVERTING LARGE-SIGNAL PULSE RESPONSE†**



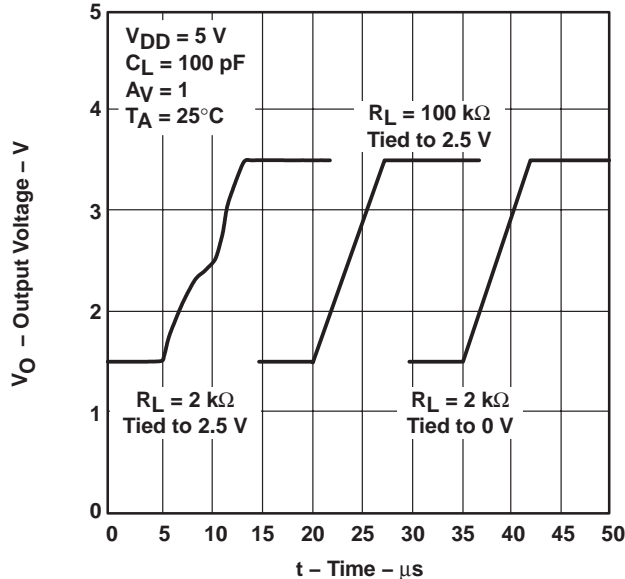
**Figure 37**

**VOLTAGE-FOLLOWER LARGE-SIGNAL PULSE RESPONSE†**



**Figure 38**

**VOLTAGE-FOLLOWER LARGE-SIGNAL PULSE RESPONSE†**



**Figure 39**

† For all curves where  $V_{DD} = 5\text{ V}$ , all loads are referenced to 2.5 V. For all curves where  $V_{DD} = 3\text{ V}$ , all loads are referenced to 1.5 V.

## TYPICAL CHARACTERISTICS

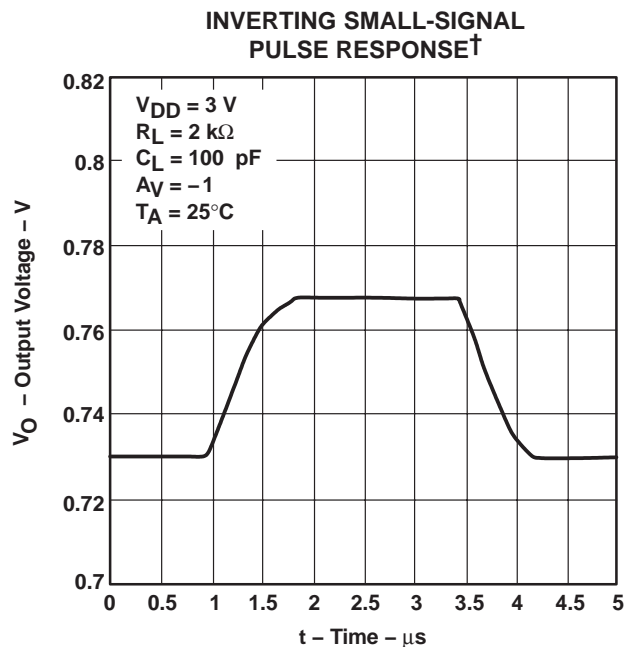


Figure 40

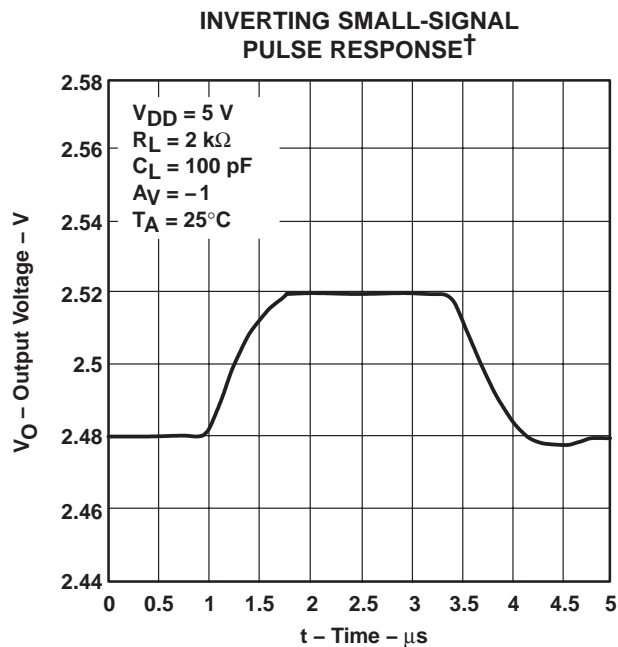


Figure 41

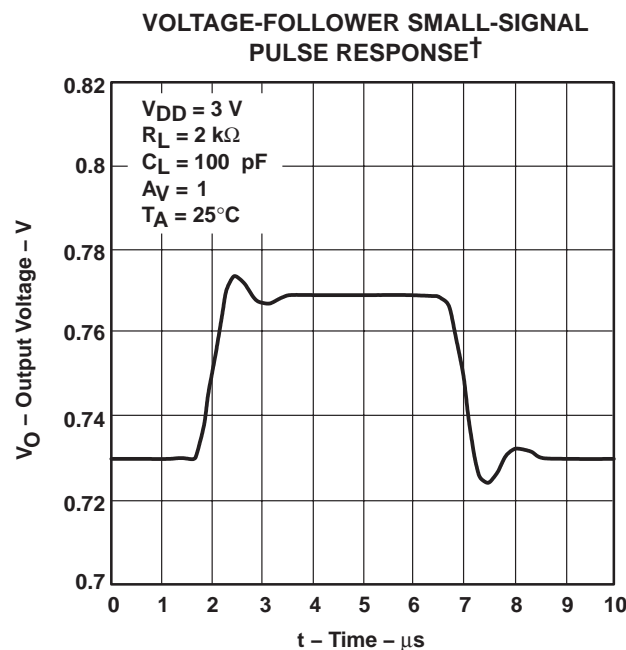


Figure 42

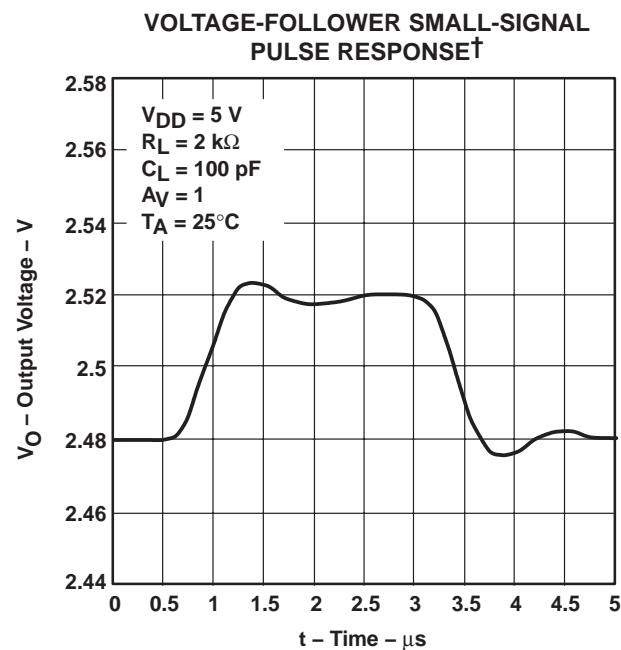


Figure 43

† For all curves where  $V_{DD} = 5\text{ V}$ , all loads are referenced to 2.5 V. For all curves where  $V_{DD} = 3\text{ V}$ , all loads are referenced to 1.5 V.

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#### TYPICAL CHARACTERISTICS

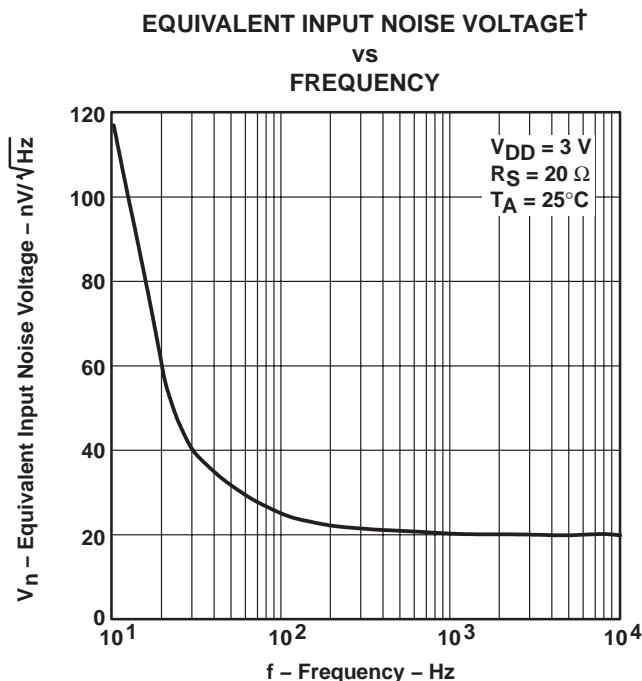


Figure 44

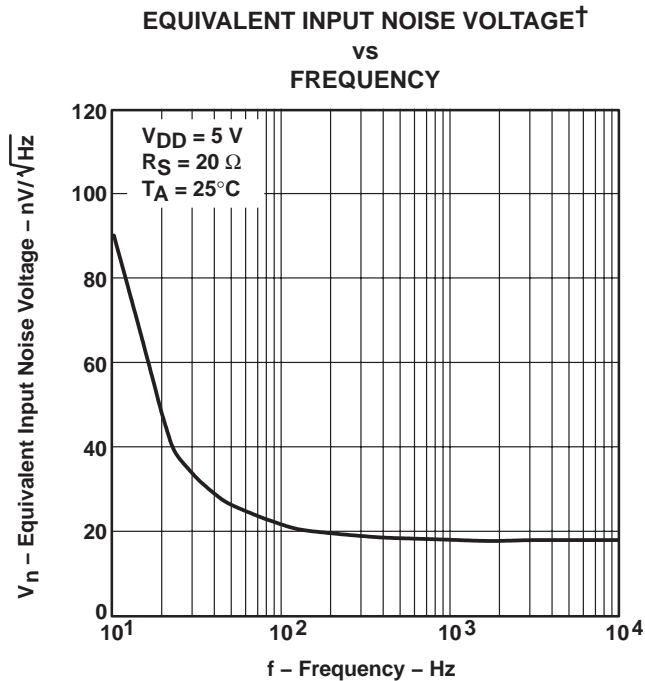


Figure 45

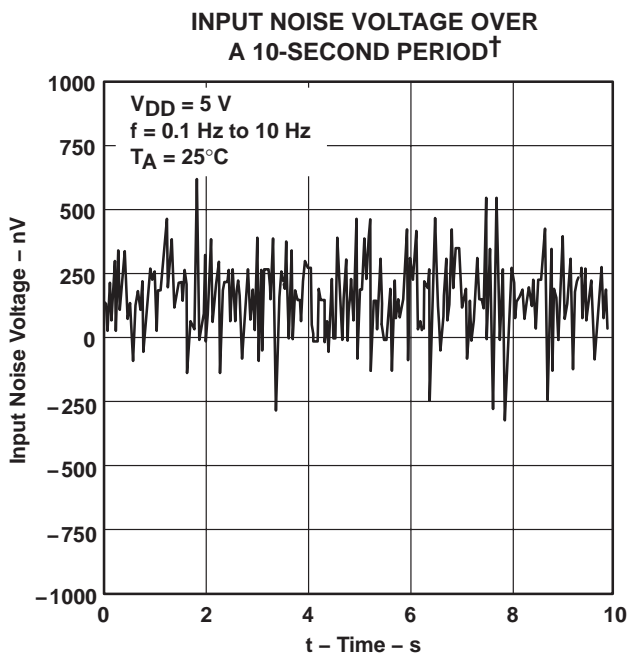


Figure 46

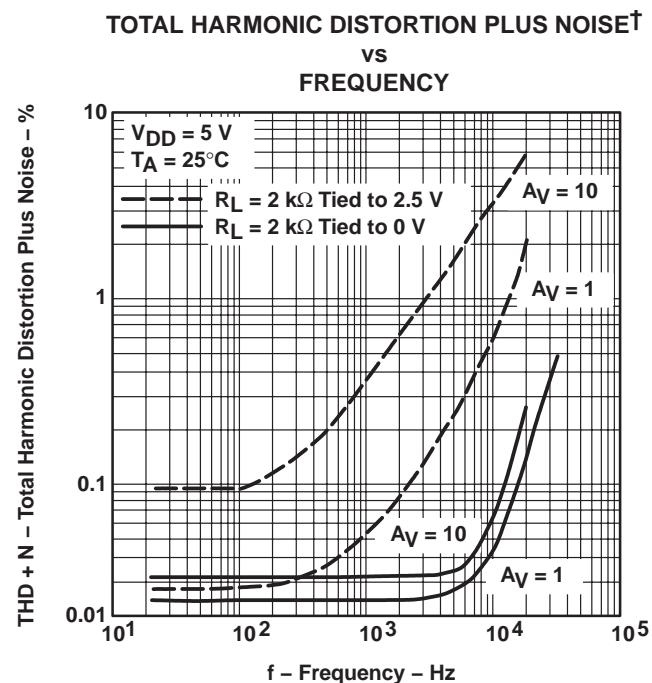


Figure 47

† For all curves where  $V_{DD} = 5\text{ V}$ , all loads are referenced to 2.5 V. For all curves where  $V_{DD} = 3\text{ V}$ , all loads are referenced to 1.5 V.

## TYPICAL CHARACTERISTICS

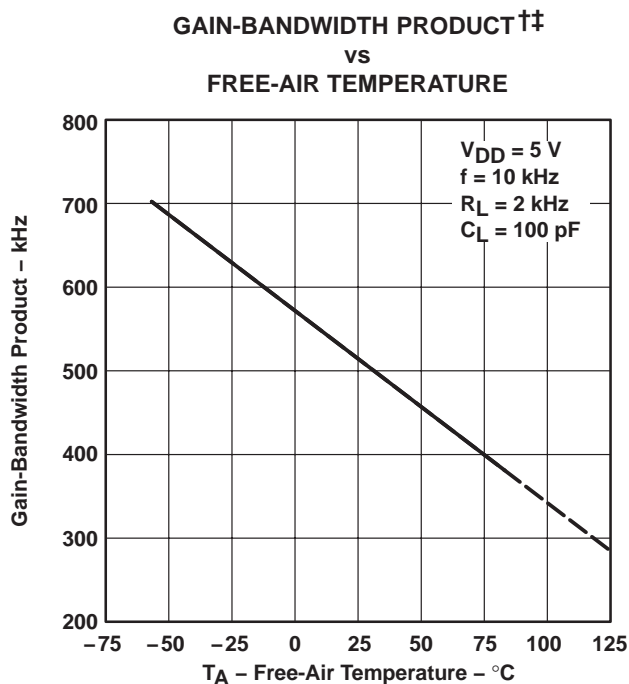


Figure 48

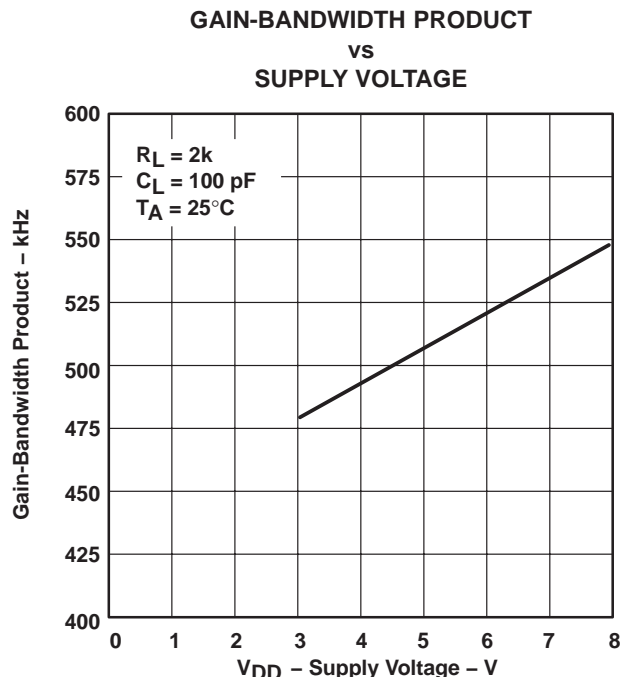


Figure 49

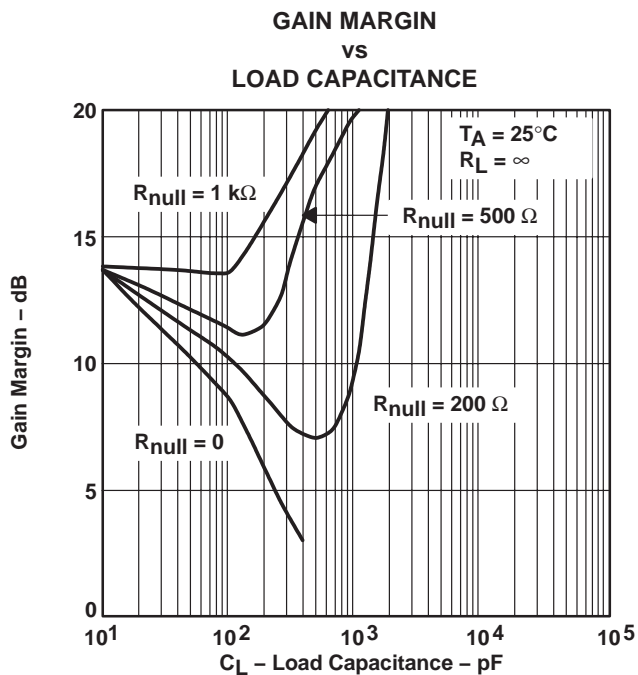


Figure 50

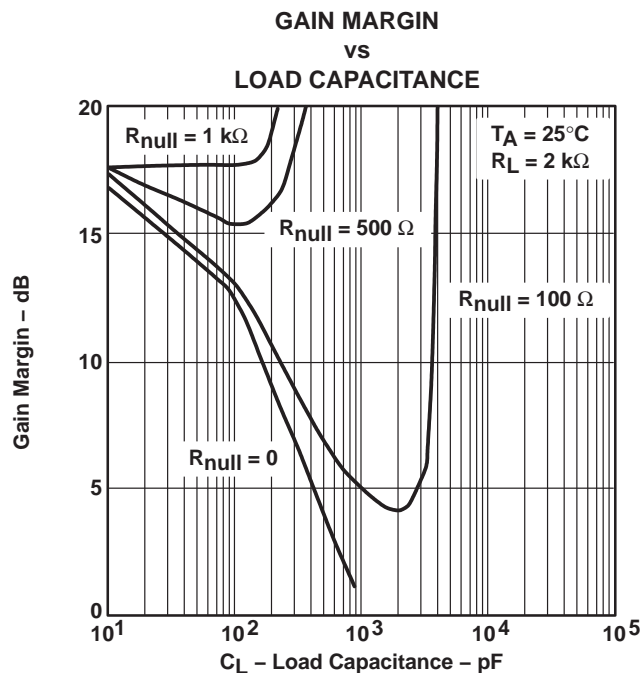
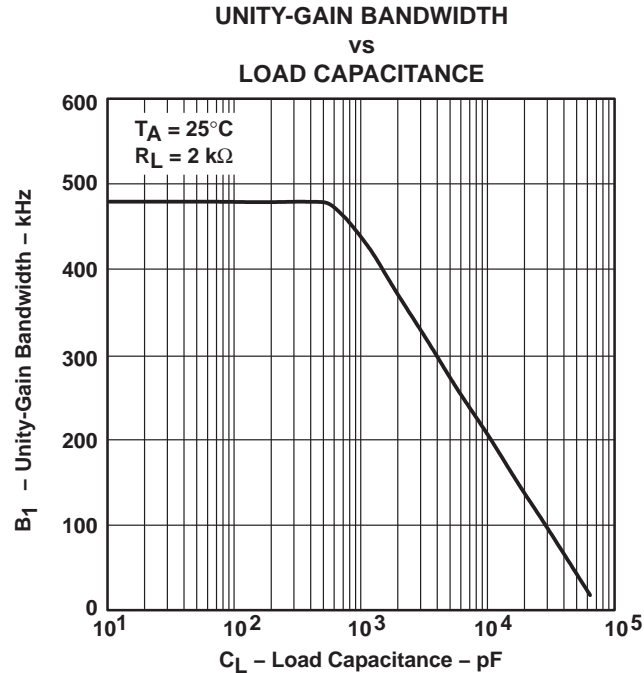
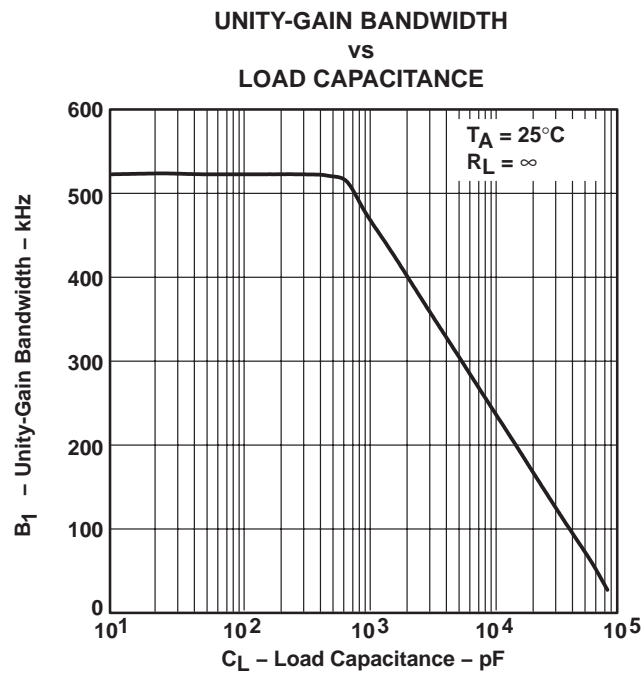
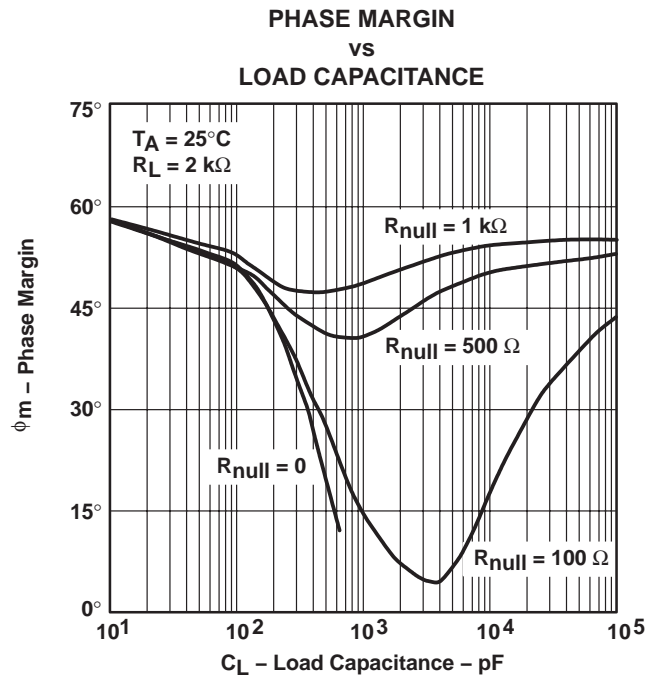
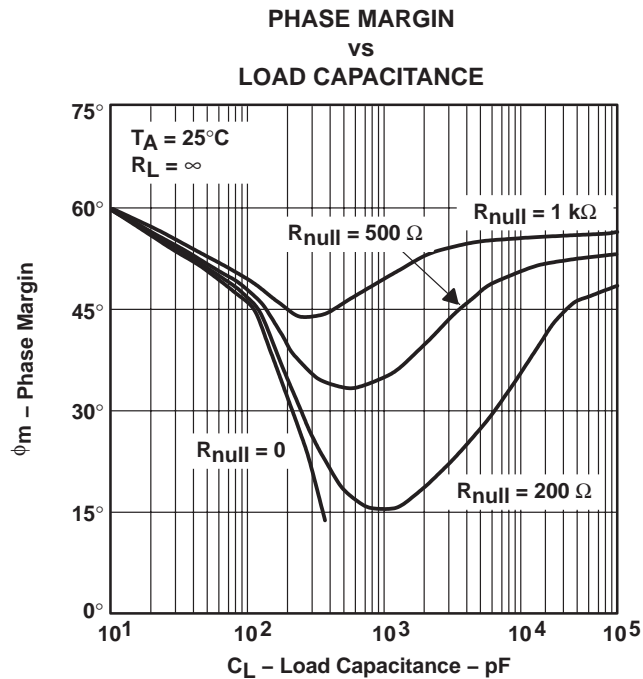


Figure 51

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

‡ For all curves where  $V_{DD} = 5\text{ V}$ , all loads are referenced to 2.5 V. For all curves where  $V_{DD} = 3\text{ V}$ , all loads are referenced to 1.5 V.

**TYPICAL CHARACTERISTICS**



## APPLICATION INFORMATION

### driving large capacitive loads

The TLV2221 is designed to drive larger capacitive loads than most CMOS operational amplifiers. Figure 50 through Figure 55 illustrate its ability to drive loads greater than 100 pF while maintaining good gain and phase margins ( $R_{null} = 0$ ).

A small series resistor ( $R_{null}$ ) at the output of the device (Figure 56) improves the gain and phase margins when driving large capacitive loads. Figure 50 through Figure 53 show the effects of adding series resistances of 100  $\Omega$ , 200  $\Omega$ , 500  $\Omega$ , and 1 k $\Omega$ . The addition of this series resistor has two effects: the first effect is that it adds a zero to the transfer function and the second effect is that it reduces the frequency of the pole associated with the output load in the transfer function.

The zero introduced to the transfer function is equal to the series resistance times the load capacitance. To calculate the approximate improvement in phase margin, equation 1 can be used.

$$\Delta\phi_{m1} = \tan^{-1} \left( 2 \times \pi \times \text{UGBW} \times R_{null} \times C_L \right) \quad (1)$$

where :

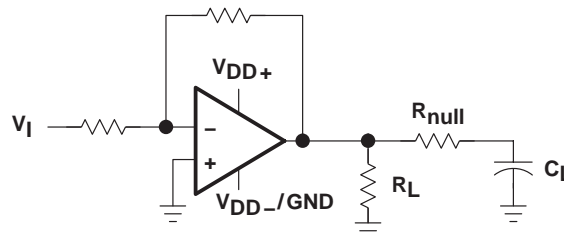
$\Delta\phi_{m1}$  = improvement in phase margin

UGBW = unity-gain bandwidth frequency

$R_{null}$  = output series resistance

$C_L$  = load capacitance

The unity-gain bandwidth (UGBW) frequency decreases as the capacitive load increases (Figure 54 and Figure 55). To use equation 1, UGBW must be approximated from Figure 54 and Figure 55.



**Figure 56. Series-Resistance Circuit**

The TLV2221 is designed to provide better sinking and sourcing output currents than earlier CMOS rail-to-rail output devices. This device is specified to sink 500  $\mu\text{A}$  and source 1 mA at  $V_{DD} = 5\text{ V}$  at a maximum quiescent  $I_{DD}$  of 200  $\mu\text{A}$ . This provides a greater than 80% power efficiency.

When driving heavy dc loads, such as 2 k $\Omega$ , the positive edge under slewing conditions can experience some distortion. This condition can be seen in Figure 38. This condition is affected by three factors:

- Where the load is referenced. When the load is referenced to either rail, this condition does not occur. The distortion occurs only when the output signal swings through the point where the load is referenced. Figure 39 illustrates two 2-k $\Omega$  load conditions. The first load condition shows the distortion seen for a 2-k $\Omega$  load tied to 2.5 V. The third load condition in Figure 39 shows no distortion for a 2-k $\Omega$  load tied to 0 V.
- Load resistance. As the load resistance increases, the distortion seen on the output decreases. Figure 39 illustrates the difference seen on the output for a 2-k $\Omega$  load and a 100-k $\Omega$  load with both tied to 2.5 V.
- Input signal edge rate. Faster input edge rates for a step input result in more distortion than with slower input edge rates.

# TLV2221, TLV2221Y

## Advanced LinCMOS™ RAIL-TO-RAIL

### VERY LOW-POWER SINGLE OPERATIONAL AMPLIFIERS

SLOS157B – JUNE 1996 – REVISED APRIL 2005

## APPLICATION INFORMATION

### macromodel information

Macromodel information provided was derived using Microsim *Parts*™, the model generation software used with Microsim *PSpice*™. The Boyle macromodel (see Note 6) and subcircuit in Figure 57 are generated using the TLV2221 typical electrical and operating characteristics at  $T_A = 25^\circ\text{C}$ . Using this information, output simulations of the following key parameters can be generated to a tolerance of 20% (in most cases):

- Maximum positive output voltage swing
- Maximum negative output voltage swing
- Slew rate
- Quiescent power dissipation
- Input bias current
- Open-loop voltage amplification
- Unity-gain frequency
- Common-mode rejection ratio
- Phase margin
- DC output resistance
- AC output resistance
- Short-circuit output current limit

NOTE 6: G. R. Boyle, B. M. Cohn, D. O. Pederson, and J. E. Solomon, "Macromodeling of Integrated Circuit Operational Amplifiers", *IEEE Journal of Solid-State Circuits*, SC-9, 353 (1974).

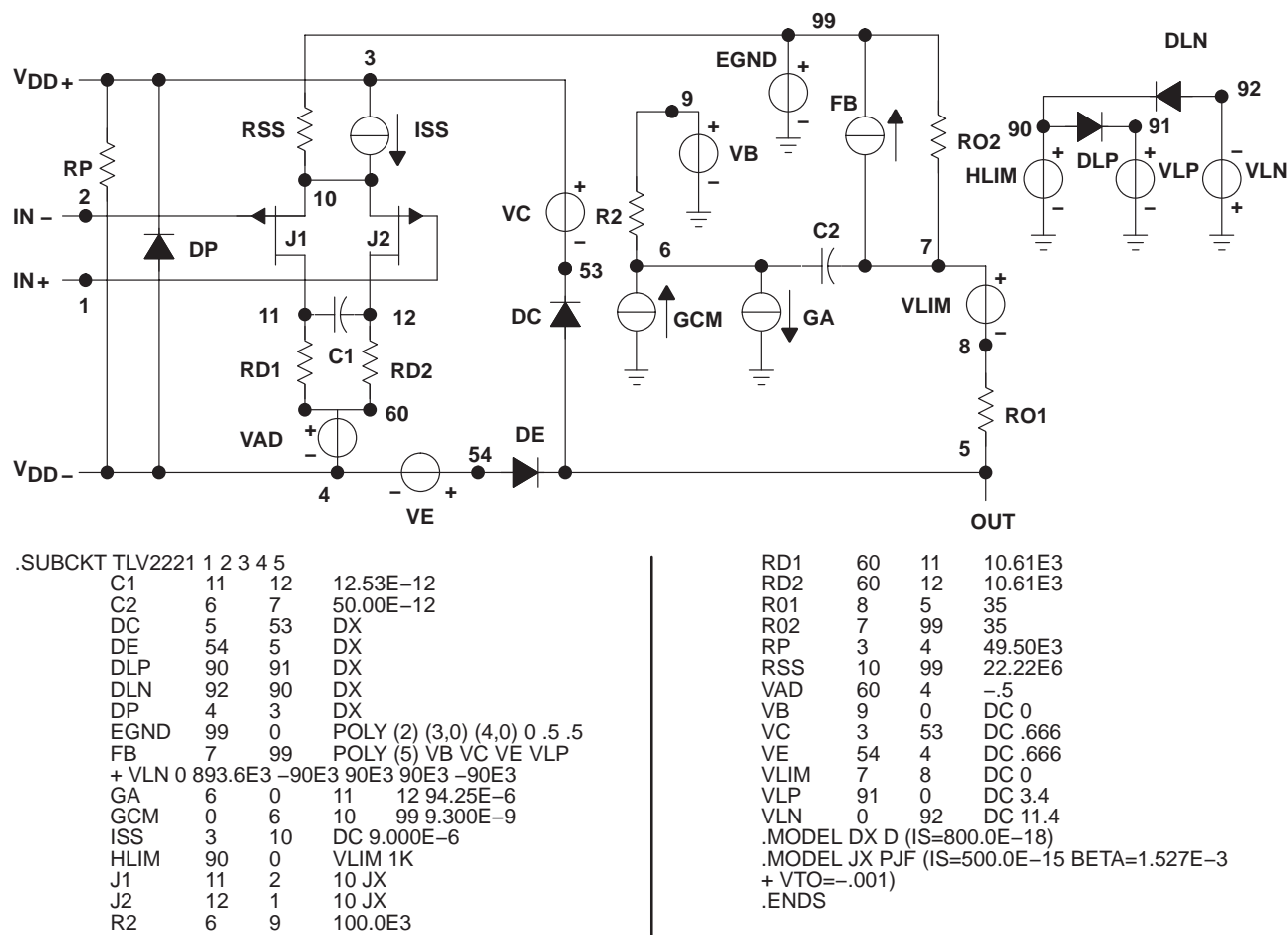


Figure 57. Boyle Macromodel and Subcircuit

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Macromodels, simulation models, or other models provided by TI, directly or indirectly, are not warranted by TI as fully representing all of the specification and operating characteristics of the semiconductor product to which the model relates.



## PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package   Pins	Package qty   Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
<a href="#">TLV2221CDBVR</a>	Obsolete	Production	SOT-23 (DBV)   5	-	-	Call TI	Call TI	0 to 70	VADC
<a href="#">TLV2221CDBVT</a>	Obsolete	Production	SOT-23 (DBV)   5	-	-	Call TI	Call TI	0 to 70	VADC
<a href="#">TLV2221IDBVR</a>	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 85	VADI
TLV2221IDBVR.A	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	VADI
TLV2221IDBVRG4	Active	Production	SOT-23 (DBV)   5	3000   LARGE T&R	-	Call TI	Call TI	-40 to 85	
<a href="#">TLV2221IDBVT</a>	Obsolete	Production	SOT-23 (DBV)   5	-	-	Call TI	Call TI	-	VADI

**(1) Status:** For more details on status, see our [product life cycle](#).

**(2) Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

**(3) RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

**(4) Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

**(5) MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

**(6) Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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## TAPE AND REEL INFORMATION



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLV2221IDBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3

## TAPE AND REEL BOX DIMENSIONS

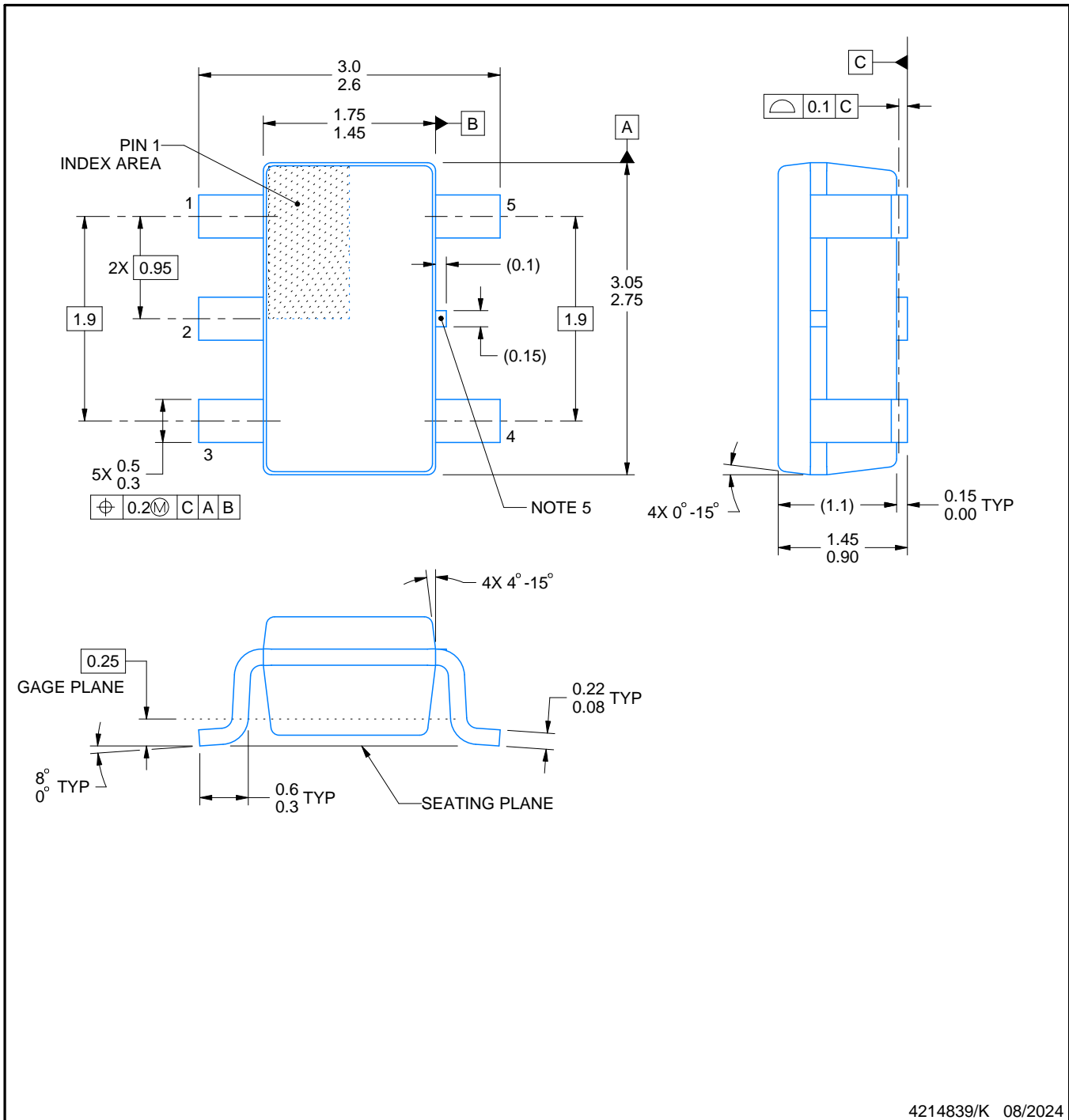


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLV2221IDBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0

**DBV0005A****PACKAGE OUTLINE****SOT-23 - 1.45 mm max height**

SMALL OUTLINE TRANSISTOR



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**NOTES:**

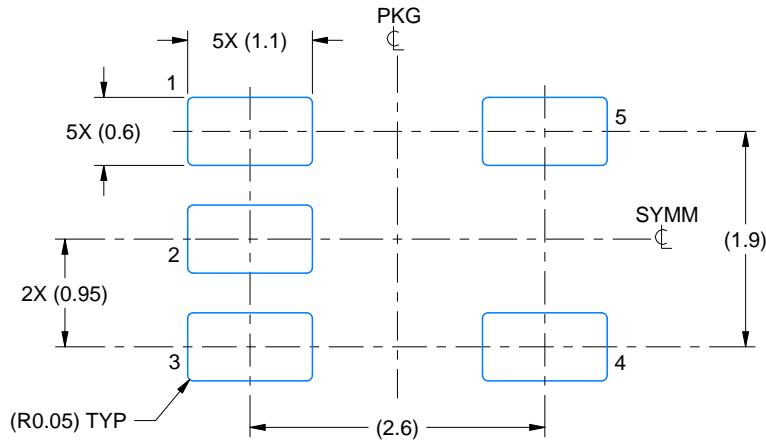
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC MO-178.
4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
5. Support pin may differ or may not be present.

# EXAMPLE BOARD LAYOUT

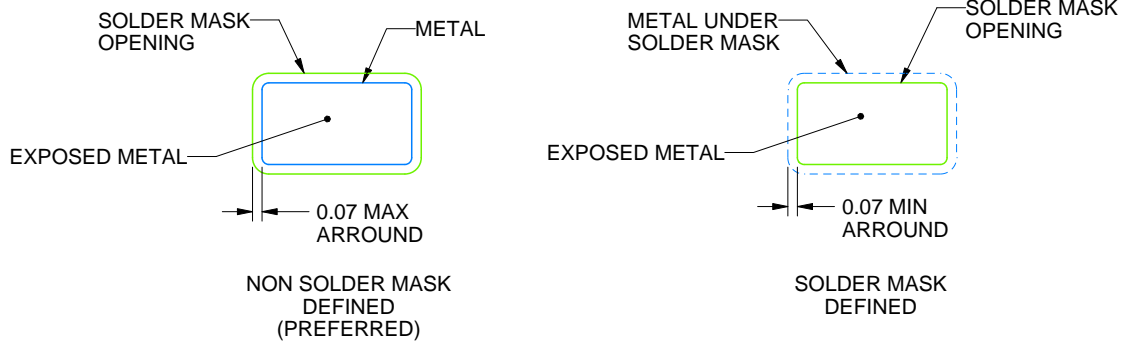
DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE:15X



SOLDER MASK DETAILS

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NOTES: (continued)

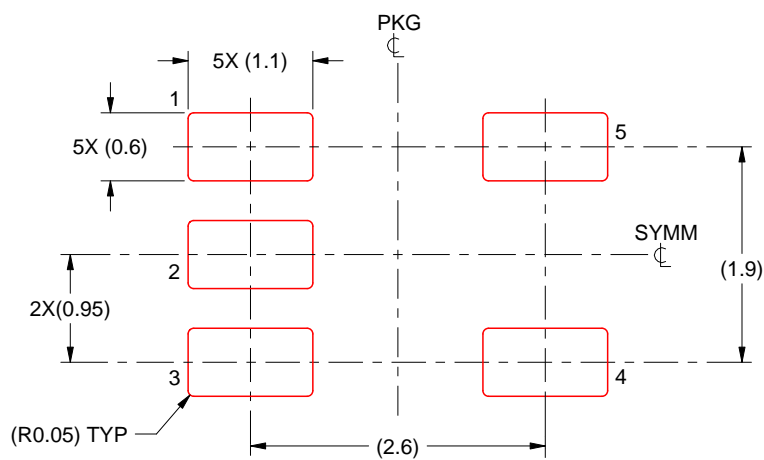
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

## EXAMPLE STENCIL DESIGN

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE:15X

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NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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